

TECHNICAL DATA



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A CATALOGUE OF MULLARD RADIO RECEIVING VALVES AND SPECIAL ELECTRON TUBES



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MULLARD OVERSEAS LTD.,
CENTURY HOUSE, SHAFTESBURY AVE., LONDON, ENGLAND.

INTRODUCTION

To millions of people throughout the world the Mullard name is associated with electronic products of the most advanced techniques and the highest quality. To those who have visited the Mullard organisation in this country, it means much more. For they have seen something of the company's extensive research facilities and great manufacturing resources.

The first few pages of this catalogue give some impression of these ramifications; we hope they will be read with interest.

For the rest, this is a catalogue of Mullard radio valves and electron tubes, and it contains descriptive details of every type in the current manufacturing programme. The most important of these to the designer of new equipment are indicated by HEAVY PRINT in the "Valve Data" section. These are the "Preferred Types" which embody the latest advances; which are in large scale production; and which will be available for maintenance for many years.

The remaining valves and tubes are, generally, normal maintenance types, the majority of which are in production or readily available from stock. A small number, however, are not being manufactured, but they have been included because they may still be available in the Trade. This means that inclusion in this catalogue of any particular type of valve or tube does not necessarily imply that it can be supplied.

It has, of course, only been possible to include abridged technical data but this should be adequate for normal requirements. Those who need more comprehensive information on the complete range of Mullard valves and tubes are invited to subscribe to the Technical Handbook Service, details of which will be found on page 66.

Advice on the use and applications of Mullard valves and electron tubes is freely available to designers and manufacturers of equipment, and to research workers. The world-wide network of Mullard distributors is constantly supplied with technical information from England, but where it is not possible for users to avail themselves of these services, they are invited to write direct to Head Office.

CONTENTS

The Mullard Organisation	pages 5-10
Alphabetical Index to Valve Data	11-13
Valve Application Index of Preferred Types	14–17
References	18
Valve Base Diagrams	19-27
Valve Data	28–51
Direct Replacement Guide	52–57
Near Equivalent Guide	58–65
The Mullard Technical Handbook Service	66



THE MULLARD ORGANISATION

The Mullard production and research organisation is the largest of its kind in the British Commonwealth. Its products range from all types of valves and electron tubes for radio, television, industry, and research to a wide variety of magnetic materials and components. For certain specialised applications complete electronic equipments are also manufactured.

The quality of these products is carefully controlled at every stage of manufacture, and in many cases processing actually starts with the raw materials. By working to these critical standards the full benefits of Mullard

research are realised in the finished products.

ELECTRONICS RESEARCH

Mullard leadership in electronics is, indeed, largely due to the unceasing work of its team of research workers. Electronics research on the broadest lines is conducted in the Mullard Research Laboratory,



situated near Redhill, Surrey. Here physicists, chemists, metallurgists, mathematicians, engineers, and glass technologists collaborate in the design and development of new and special electron tubes, and new techniques and processes. Here, too, investigations are made of specific problems affecting the applications of electronics to other branches of research, and to the fields of industry, communications, and medicine.

Two other vitally important links in the Mullard research organisa-

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made into the physical and chemical properties of the great variety of materials used in the manufacture of electron tubes. This laboratory also provides a comprehensive service on materials to the Mullard factories in solving production problems and improving manufacturing processes.

WIRE AND GLASS MANUFACTURE

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This emphasis on the quality of materials is vitally necessary in view of the high performance and reliability demanded of modern valves and electron tubes. To maintain the highest possible standard in the finished products it is essential to control the quality of raw materials at the earliest possible stage. The wire and glass used in Mullard valves and tubes, for example, are produced from the actual raw materials in the company's own factories at Blackburn. In this way it is not only possible to control quality throughout every stage of manufacture, but also to ensure continuity of supply.

On an average, more than five million yards of fine wire—tungsten for valve filaments, and molybdenum for grids, filament supports, and mandrils—are produced at the Blackburn plant each week. Some of this will be less than 8 microns (3/10,000th inch) diameter or 1/10th the thickness of an average human hair.

The manufacture of this wire is a fine example of the application of science to modern industry. Through a long and elaborate series of operations, a handful of powder is transformed into miles of wire, every inch of which conforms to the most exacting standards. To ensure that these high standards are maintained, the diamond dies, through which the finer wire is drawn, are also manufactured at Blackburn.

The manufacture of glass for electron tubes also involves a number of highly technical operations. In the Mullard glass plant, the raw materials—silica (sand), soda ash, potash and red lead—are converted into thousands

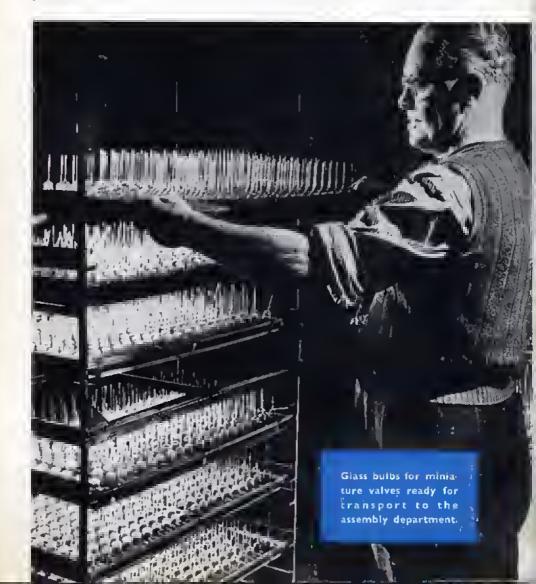


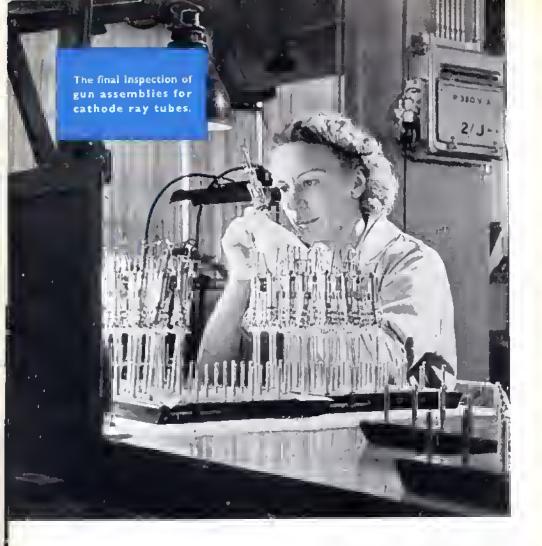
of feet of glass tubing having a wall thickness controlled to tolerances as close as 1/500th inch.

From these standard "sticks" of tubing the bulbs and bases for the latest all-glass valves are made, as well as parts for the older, pinch-type valves. The Blackburn glass factory produces millions of glass components every year for distribution to the various valve production units within the Mullard organisation. Some of the glass parts for cathode ray tubes are also made here, and glass bulbs for the tubes are assembled in large quantities.

VALVE PRODUCTION

The strict control of quality, applied throughout the raw material stage, is continued in the manufacture of valve and cathode ray tube components—filaments, grids, anodes, mica discs, etc. With few exceptions,





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these parts are produced on intricate machines, designed and constructed in the company's own engineering department.

The highly skilled operations involved in assembling the components can only be carried out by hand. A high degree of mechanisation, however, is again employed in sealing the assemblies into their glass envelopes, and then exhausting these to a hard vacuum.

Careful inspections are made at every stage of manufacture and the finished products are subjected to rigorous production tests. Before the valves and eathode ray tubes are released for use, however, further intensive tests are carried out in specially-equipped technical departments.

The two main Mullard production units situated in Lancashire and Surrey, supported by five feeder factories, produce a major portion of the total output of valves and electron tubes made in the British Isles. Whilst radio valves and television picture tubes account for the greater part of the Mullard output, special tubes for industrial, medical, and research applications are also produced in vast quantities.

ALPHABETICAL INDEX TO VALVE DATA

ТҮРЕ	Base Diagram No.	PAGE	TYPE	Base Diagram No,	PAGE	TYPE	Base Diagram No.	PAGE
AB2	129	33	DF21	133	28	DP13-2	163	44
ABC1	45	36	DF22	133	28	DR7-5	162	44
ABLI	50	40	DF33	67	28	DR7-6	162	44
ACO44	3	34	DF66	121	28	DW2	1	41
AF3	47	28	DF70	16	28	DW4/350	ι	42
AF7	47	28	DF9I	3B	28	DW4/500	1	42
AK2	33	31	DF92	38	28	EA50	118	33
AL4	46	36	DG4-I	162	44	EAC91	36	36
AZI	43	41	DG4-2	162	44	EAF42	93	31
AZ4	43	41	DG7-5	162	44	EB4	139	33
AZII	130	41	DG7-6	162	44	EB34	58	33
AZ12	130	41	DG13-2	163	44	EB4I	92	33
AZ31	55	41	DK2I	134	31	EB9l	37	34
AZ4I	131	41	DK32	77	31	E8C3	45	36
CBLI	50	40	DK40	135	32	EBC33	62	36
CBL31	75	40	DK91	41	32	EBC4!	97	36
CCH35	82	31	DK92	21	32	EBF2	140	31
CL4	48	36	DL21	136	37	EBFII	141	31
CL33	70	36	DL33	69	37	EBF32	75	31
IYO	42	41	DL35	66	37	EBF80	103	31
CY31	53	41	DL36	66	37	EBLI	50	40
DA90	113	33	DL4I	137	37	EBL21	87	40
DAC21	132	36	DL66	121	37	EBL31	75	40
DAC32	65	36	DL68	121	37	EC31	60	34
DAF9I	40	31	DL71	16	37	EC52	89	34
DB4-I	162	44	DL72	16	37	EC53	120	34
DB4-2	162	44	DL92	39	37	EC54	15	34
DB7-5	162	44	DL 9 3	115	37	EC91	59	34
DB7-6	162	44	DL94	30	37	ECC31	142	34
DB13-2	163	44	DLL21	138	37	ECC32	64	34
DCC90	D4	34	DP4-I	162	44	ECC33	64	34
DDR100	164	51	DP4-2	162	44	ECC34	64	34

ALPHABETICAL INDEX TO VALVE DATA

TYPE	Base Diagram No.	PAGE	TYPE	Base Diagram No.	PAGE	TYPE	Base Diagram No.	PAGE
ECC35	64	35	EK2	33	32	HLI3C	19	35
ECC40	100	35	EK32	81	32	HVR2	2	42
ECC81	63	35	EL2	48	37	HVR2A	2	42
ECC91	80	35	EL3	46	38	IW4/350	7	42
ECFI	143	28/35	ELII	146	38	IW4/500	7	42
ECH3	52	32	EL12	146	38	KB2	129	34
ECHII	144	32	EL31	73	38	KBCI	153	36
ECH21	88	32	EL32	71	38	KBC32	61	36
ECH33	82	32	EL33	70	38	KCF30	170	32
ECH35	82	32	EL34	149	38	KF3	154	29
ECH42	94	32	EL35	70	38	KF35	68	29
ECLII	145	35/37	EL37	70	38	KK2	155	33
ECT80	102	35/37	E£38	73	38	KK32	79	33
ECR30	165	44	EL41	96	38	KL4	156	38
ECR35	166	44	EL42	96	38	KL35	66	38
ECR35P	166	44	EL81	122	38	KLL32	84	38
ECR60	166	44	EL91	78	38	LSD2	167	46
EF9	47	28	EMI	150	41	L\$D3	110	46
EFII	146	28	EM4	51	41	LSD3A	111	46
EF12	146	28	EM34	76	41	LSD4	112	46
EF22	86	28	EN31	83	45	LSD5		47
EF36	72	29	EQ80	151	40	LSD7	110	47
EF37	72	29	EY5I	119	42	LSD8	168	47
EF37A	72	29	EY91	54	42	LSD9	110	47
EF39	72	29	EZ2	152	42	LSDIO		47
EF40	98	29	EZ35	56	42	LSD12		47
EF41	96	29	EZ40	5	42	LSD13	-	47
EF42	95	29	EZ4I	5	42	LSD14	-	47
EF50	90	29	FC2A	32	32	LSD15		47
EF54	91	29	FC4	34	32	LSD16	-	47
EF55	90	29	FC13	33	32	LSD17	-	47
EF80	104	29	FC13C	34	32	LSD18	_	47
EF91	74	29	FW4/500	1	42	MEI001	169	50
EF92	74	29	FW4/800	1	42	ME1005	169	50
EF95	147	29	GZ32	57	42	MEI 100	-	51
EFMI	148	41	HLI3	44	35	MELIOI	J -	51

ALPHABETICAL INDEX TO VALVE DATA

TYPE	Base Diagram No.	PAGE	TYPE	Base Djagram No.	PAGE	TYPE	Base Diagram No.	PAGE
MEI200AA	171	49	PY80	124	42	UR3C	18	43
MEI20IAA	172	50	PY81	185	42	UYIN	160	43
MEI202CA	173	50	PY82	124	43	ווצע	161	43
ME1400	72	51	PZ30	17	43	UY21	85	43
ME1401	174	51	QP22B	35	39	UY4I	14	43
ME1503	175	45	SP2	24	29	VP2	24	30
MFI3-I	176	45	SP4	13,27	30	VP2B	28	30
MF31-22	116	45	SP4B	26	30	VP4	13,27	30
MTI7	177	46	SP13	47	30	VP4A	13, 27	30
MT57	178	46	SP13C	26	30	VP48	26	30
MTI05	179	46	TDD2A	10	36	VP13A	47	30
MT5544	180	46	TDD4	20	36	VPI3C	26	30
MT5545	180	46	TDD13C	20	36	2D4A	8	34
MW6-2	117	45	TH48	31	33	2D21	181	46
MW31-16	116	45	TH21C	31	33	20AV	106	48
MW36-22	116	45	TH30C	31	33	20CG	107	48
MW4I-I	116	45	UAF42	93	31	20CV	107	48
PENA4	25	38	U84I	92	34	52CG	125	48
PEN84	25	38	U8C4I	97	36	55CG	126	48
PEN4DD	29	40	UBFII	141	31	57CV	182	48
PEN4VA	12, 25	39	U8F80	103	31	58CG	183	48
PEN36C	25	39	U811	157	40	58CV	183	48
PL33	70	39	UBL2I	87	40	85AI	127	43
PL38	73	39	UCHII	144	33	85A2	128	43
PL81	122	39	UCH21	88	33	90AG	108	49
PL82	123	39	UCH42	94	33	90AV	108	49
PL83	105	39	UCLII	145	35/39	90CG	109	49
PM2A	3	35	UF9	158	30	90CY	109	49
PM2HL ·	3	35	UFII	146	30	15082	186	43
PM12M	4	29	UF21	86	30	354V	9	35
PM22A	- 11	39	UF41	96	30	1267	184	46
PM22D	- 11	39	UF42	95	30	4687	49	43
PM24A	- 11	39	UL4I	96	39	4687A	23	43
PM24M	- 11	39	UM4	159	41.5	7475	23	43
PM202	3	35	UM34	76	41	13201A	23	43
PY31	53	42	URIC	6	43			

VALVE APPLICATION INDEX OF PREFERRED TYPES

TYPE	Vh or Vf (V)	Ih or If (A)	DESCRIPTION	PAGE
VDLTAGE	A MDI IEV	ING DE	NTDDEC	
DF66	0.625	l 0:015 l		1 28
DF91	1.4	0.013	Hearing-aid pentode. Varíable-mu R.F. pentode.	28
DF92	1.4	0.05	Short grid base R.F. pentode.	28
EF37A	6.3	0.2	Low microphony, low hum A.F. pencode.	29
EF40	6.3	0.2	Low noise A.F. pentode.	29
EF41	6.3	0.2	Variable-mu R.F. pentode.	29
EF80	6.3	0.3	High slope R.F. pentode.	29
EF95	6.3	0.175	High slope R.F. pentode.	29
UF4I	12.6	0-1	Variable-mu R.F. pentode.	30
DLTAGE	AHPLIFY	ING PEN	NTDDES WITH DIDDES	
DAF91	1 1.4 1	0.05 (Short grid base A.F. pentode with single diode.	31
EBF80	6.3	0.3	Variable-mu R.F. pentode with double diode.	31
UBF80	17	0-1	Variable-mu R.F. pentode with double diode.	1E
REQUEN	CY CHAN	IGERS		
DK92	1.4	0.05	Heptode.	32
ECH42	6-3	0.23	Triode hexode,	32
UCH42	14	0-1	Triode hexode.	33
INGLE A	ND DDU	BLE DIDE	DES	
DA90	-4	0-15	Indirectly heated single dlode.	33
EB91	6-3	0-3	Double diode with separate cathodes.	34
TRIDDES A	AND DDI	UBLE TR	ID DES	
DCC90	\ \begin{cases} 1.4 \\ 2.8 \end{cases}	0·22 0·11 }	R.F. double triode, suitable for portable trans- mitters.	34
ECC33	6.3	0.4	A.F. double triode with separate cathodes,	34
ECC35	6.3	0-4	A.F. double triode with separate cathodes.	35
ECC40	6.3	0.6	A.F. double triode with separate cathodes.	35
ECC81	{ 6·3 12·6	0.3	R.F. double triode with separate cathodes.	35
ECC91	6.3	0.45	R.F. double triode with common cathode.	35
ECL80	6.3	0.3	Triode combined with output pentode.	35
TRIDDES '	WITH DI	DDES		
EBC4I	I 6·3	0.23	Double diode triode.	36
UBC41	14	0.1	Double diode triode.	36
	,		14	

VALVE APPLICATION INDEX OF PREFERRED TYPES

TYPE	Vh or Ví (V)	Ih or If (A)	DESCRIPTION	PAGE
DUTPUT	PENTODE	•		_
DL66	1.25	- 0:015	Hearing-aid output pentode.	1 37
DL68	1.25	0.015	Hearing-aid output pentode. Hearing-aid output pentode.	37
	(1.4	0.1 3	- ' '	
DL92	2.8	ŏ.os }	A.F. output pentode.	37
DL93	\ \{ 1.4 \ 2.8 \	0.2	R.F. or A.F. output pentode.	37
DL94	{ 1.4 2.8	0.1	A,F, output pentode,	37
ECL80	6.3	0.3	Output pentode (pa max,=3.5 W) combined with triode	37
EL37	6.3	1.4	Output pentode (pa max.=25 W).	38
EL38	6.3	1.4	Line time base output pentode.	38
EL41	6.3	0.7	Output pentode (pa max, = 9 W)	38
EL42	6.3	0.2	Output pentode (pa max.=6 W).	38
EL81	6.3	1.05	Series stabiliser and line time base output pentode.	38-
PL8I	21.5	0.3	Line time base output pentode.	39
PL82	16.5	0.3	Output pentode (pa max, =9 W),	39
PL83	15	0.3	Video output pentode,	39
UL4I	45	0.1	Output pentode (pa max.=9 W).	39
NDNDDE				
EQ80	6.3	0·2	F.M. detector and limiter.	40
ELECTRON	BEAM	TUNING	INDICATOR	
EM34	6.3	0.2	Dual sensitivity tuning indicator,	4
RECTIFIER	ıs			
EY5I	6.3	0.09	High voltage rectifier for E.H.T. supplies.	42
EZ40	6.3	0.6	Indirectly heated full-wave rectifier.	42
EZ41	6.3	0.4	Indirectly heated full-wave rectifier.	42
GZ32	5.0	2.3	Indirectly heated full-wave rectifier.	42
PY80	19	0.3	Booster diode.	42
PY81	17	0.3	Booster diode.	42
PY82	19	0.3	Indirectly heated half-wave rectifier.	43
UY4I	31	0-1	Indirectly heated half-wave rectifier,	43
GAS-FILLE	D TRIOD	ES AND	TETRODES	
ME1503	1 6.3	3.75	Hydrogen-filled triode.	45
MT17	2.5	5.0	Mercury-vapour triode.	46
MT57	5.0	4.5	Mercury-vapour triode.	46
MT105	5-0	10	Mercury-vapour tetrode.	46
MT5544		12	Inert-gas-filled triode.	46
MT5545		21	Inert-gas-filled triode,	46
2D21	6.3	0.6	Inert-gas-filled tetrode,	46
1267		athode	Inert-gas-filled triode.	46

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VALVE APPLICATION INDEX OF PREFERRED TYPES

64

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TYPE	DESCRIPTION	N PAG	GE
VOLTAGE REF	RENCE AND STABILIZING T	UBES	
85A1	85-volt Voltage reference tube.	' 4:	3
85A2	85-volt Voltage reference tube.	41	3
150B2	150-volt Voltage stabilizer.	4:	3
CATHODE RA	TUBES		
DB4-I	13 in. Oscilloscope, Blue screen.	Symmetrical. 4	4
DB4-2	13 In. Oscilloscope. Blue screen.	Asymmetrical. 44	4
DB7-5	23 in. Oscilloscope. Blue screen.	Symmetrical.	4
DB7-6	23 in. Oscilloscope, Blue screen.	Asymmetrical. 44	4
DB13-2	5 in. Oscilloscope, Blue screen.	Symmetrical. 44	4
DG4-I	13 in. Oscilloscope. Green scree	n. Symmetrical. 44	4
DG4-2	la in. Oscilloscope. Green scree	n. Asymmetrical. 44	4
DG7-5	23 in. Oscilloscope. Green scree	n, Symmetrical. 44	4
DG7-6	23 in. Oscilloscope. Green scree	n. Asymmetrical. 44	4
DG13-2	5 in. Oscilloscope. Green scree	n. Symmetrical. 44	4
DP4-I	13 in. Oscilloscope. Long aftergle	ow. Symmetrical. 44	4
DP4-2	13 in. Oscilloscope. Long aftergle		4
DPI3-2	5 in. Oscilloscope. Long aftergle	ow. Symmetrical. 44	4
DR7-5	23 In. Oscilloscope. Long aftergle		4
DR7-6	23 in. Oscilloscope. Long aftergle	ow. Asymmetrical. 44	4
MFI3-I	5 in. Radar. Orange scre		5
MF31-22	12 in. Radar. Orange scre	41	5
MW6-2	2½ ln. Projection television.	Metal-backed. 45	5
MW31-16	12 in. Television.	lon-trap. 43	5
MW36-22	14 in. Television. Rectangular.	. lon-trap. 43	5
MW41-1	16 in. Television. Metal cone.	Ion-trap. 4	5
FLASH-TUBES			
LSD2	35 joule Microsecond flash-tube.	46	6
LSD3	100 joule Photographic flash-tube.	40	6
LSD5	1,000 joule Photographic flash-tube.	47	7
LSD7	200 joule Photographic flash-tube.	47	7
LSD8	Stroboscopic tube. 30 W mean dis	ssipation. 47	7
PHOTOCELLS	·		
20CG	Gas-filled. Incandescent light and in	nfra-red radiation. 48	8
20CV	Vacuum. Incandescent light and in	nfra-red radiation. 48	8
52CG	Gas-filled. Incandescent light and i		8
55CG	Gas-filled. Incandescent light and i		8
57CV	Photometric cell.	48	8
58CG	End-on wire-in. Gas-filled. Incar radiation.	ndescent light and infra-red 48	8
58CV	End-on wire-in. Vacuum. Incand radiation.	descent light and infra-red 48	3
90AG	Gas-filled. Daylight and blue radiat	ion. 49	9
90AV	Vacuum. Daylight and blue radiation	on. 49	9
90CG	Gas-filled. Incandescent light and in		9
90CV	Vacuum, Incandescent light and inf		9

VALVE APPLICATION INDEX OF PREFERRED TYPES

TYPE	DESCRIPTION	PAGE
U.H.F. TUBES		,
ME1001	Disc seal triode oscillator.	1 50
ME1005	Disc seal triode voltage amplifier,	50
MEI 100	3 cm. local oscillator reflex klystron,	51
MEIIOI	3 cm. fixed frequency packaged magnetron,	51
IMAGE CONV	ERTER TUBES	
ME1200AA	Image converter. Daylight and blue radiation.	1 49
ME1201AA	Grid-controlled image converter. Daylight and blue radiation.	50
ME1202CA	Small image-converter. Infra-red radiation,	50
	Variants of these tubes with different photocathodes and luminescent screens are also available.	
ACCELEROMET	ER TUBE	
DDR100	Accelerometer double diode.	51
ELECTROMETE	R VALVES	
ME [400	Electrometer pentode.	1 51
ME1401	Subministura alectromeros rejeda	EI

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REFERENCES

a Anode. C.R.T. anodes marked al, a2, etc., al being nearest the cathode.

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- g Grid. Grids marked gl, g2, etc., gl being nearest the cathode.
- k Cathode.
- f Filament.
- h Heater.
- s Internal shield.
- M External metallising.
- T Trigger electrode (Flash-tubes).
- IC Internal connection; not to be used for external connections.
- Va Anode voltage.
- Vg2 Screen grid voltage.
- Vgl Control grid voltage.
 - Vf Filament voltage.
- Vh Heater voltage.
- va(pk) Peak anode voitage.
- P.I.V. Peak inverse voltage.
 - la Anode current.
 - 1g2 Screen grid current.
 - If Filament current.
 - Ih Heater current.
 - it Target current.
 - lout Output current.
- ia(pk) Peak anode current.
- Pout Output power.
 - pa Anode dissipation.
 - Ra External anode load.
 - Rk Cathode bias resistor.
 - ra Internal anode impedance.
 - μ Amplification factor.
 - gm Mutual conductance.
 - gc Conversion conductance.
 - S Sensitivity (cathode ray tubes).

BASE REFERENCES

- A British 4-pin.
- K International octal.
- M British 7-pin.
- MO Mazda octal.
 - O British 5-pin.
 - P Side contact (8-contact).
- UX American base.
 - V Side contact (5-contact).
 - Y European 8-pin.
- B2A 2 wire-in leads.
- B3A American Pee-wee 3-pin.

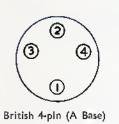
B3G 3-pin all-glass.

Not applicable to frequency changers

with additional oscillator electrodes.

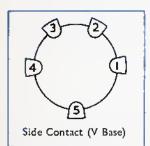
- B4D Super Jumbo 4-pin.
- BSA Flat subminiature.
- B7G 7-pin miniature.
- BBA 8-pin miniature.
- B8D 10 mm, round subminiature.
- B8G Loctal.
- B9A 9-pin miniature (noval).
- B9G 9-pin all-glass.
- BI2A Duodecal.
- BI4A Diheptal.

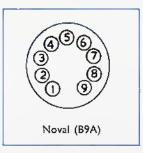
viewed from free end of pins



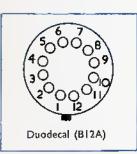
3 (3 (4)
(1)
British 5-pin (O Base)

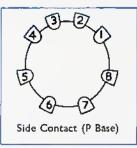


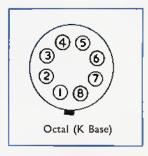




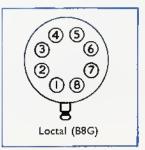




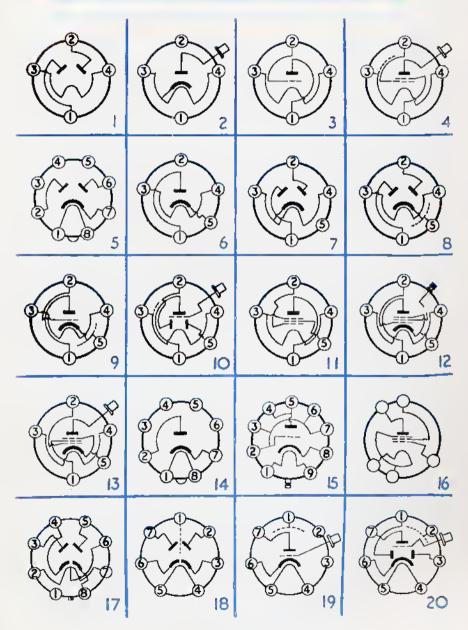


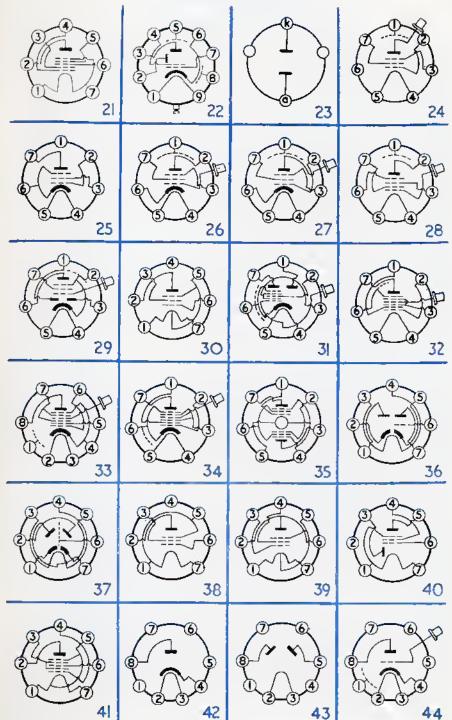


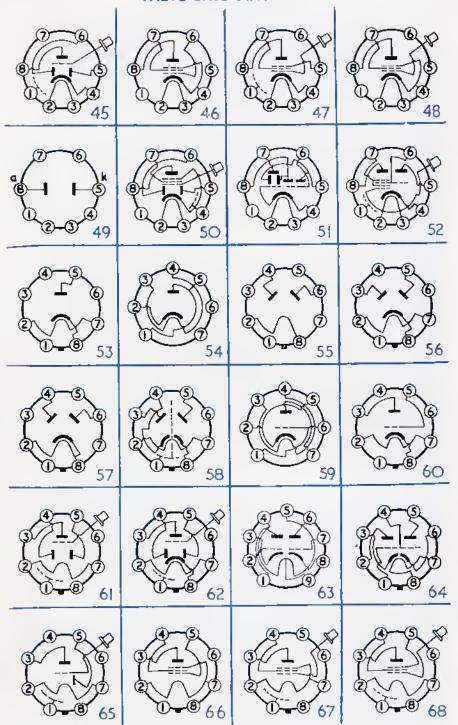


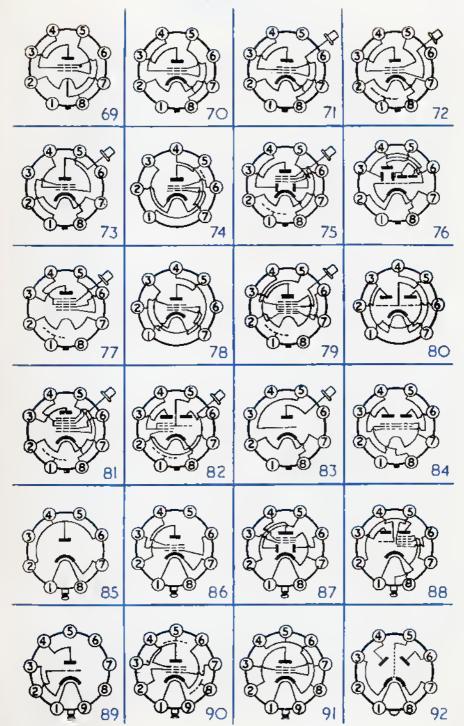


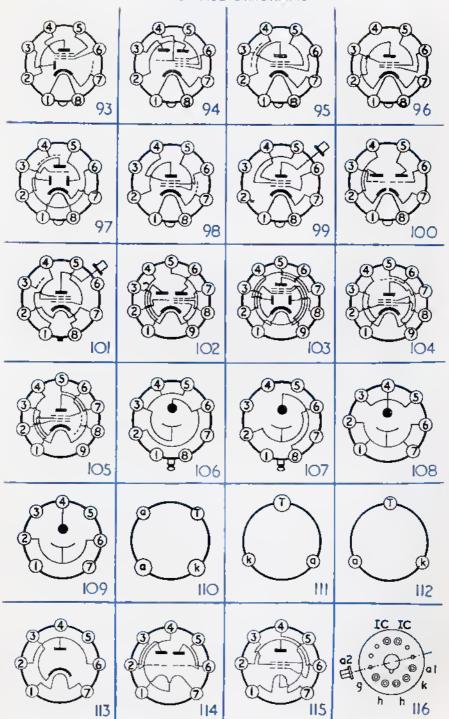


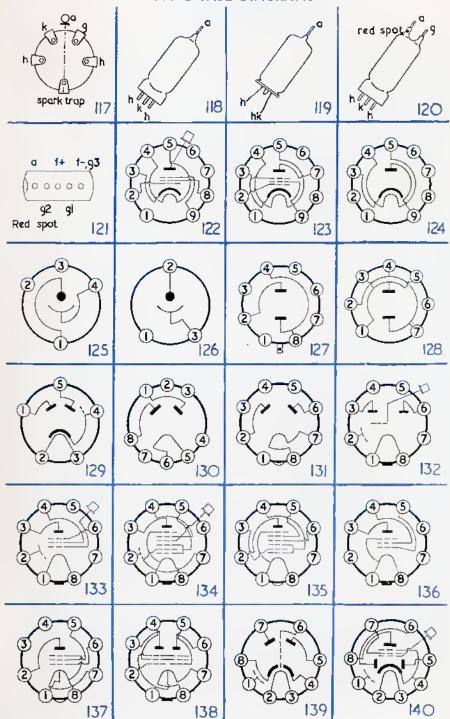


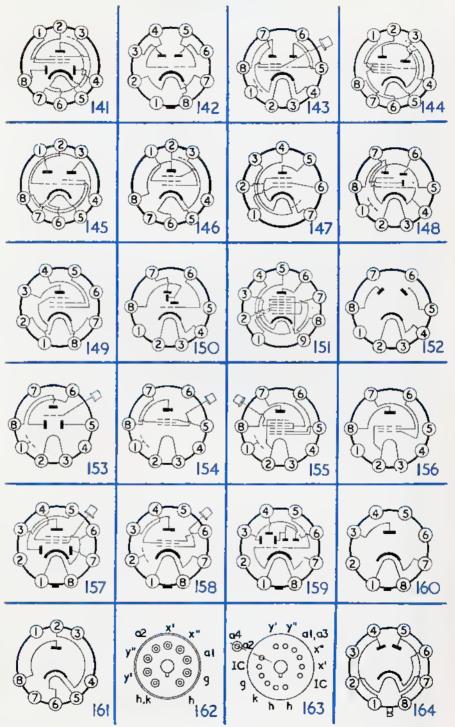


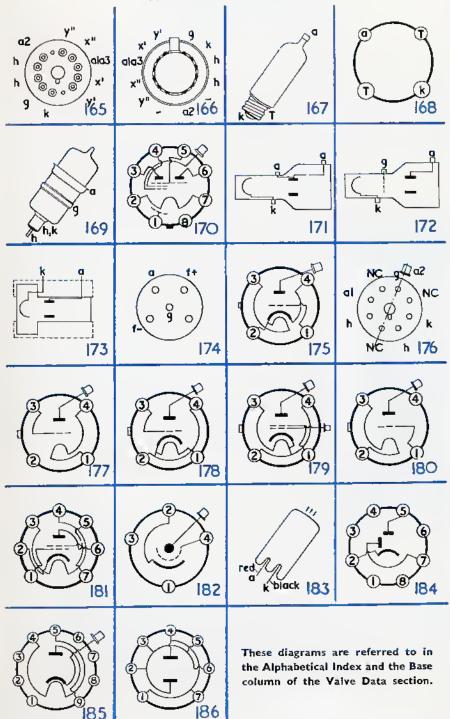












VALVE DATA

VOLTAGE AMPLIFYING PENTODES

TYPE	DESCRIPTION			BA	ASE	Vfor Vh (V)	If or Ih (A)	(V)	Vg2 (V)	- V g1	la (mA)	lg2 (mA)	gm (mA/V)	ra (M Ω)
AF3	Variable-mu R.F. Pentode			P.	(47)	4.0	0.65	250	100	3.0	8.0	2.6	1.8	1.2
AF7	Short Grid Base R.F. Pentode			P.	(47)	4.0	0.65	250	100	2.0	3.0	1:1	2.1	2.0
DF21	Short Grid Base R.F. or A.F. Pentor	de		Octal	(133)	1.4	0.025	90	90	0	1.2	0.25	0.7	2.0
DF22	Variable-mu R.F. Pentode			Octal	(133)	1.4	0.05	90	90	1.5	1.4	0.3	1:1	1.5
DF33	Variable-mu R.F. Pentode			Octal	(67)	1.4	0.05	90	90	0	1.2	0.3	0.75	1.5
DF66	Hearing-ald Pentode			B5A	(121)	0.625	0.015	22.5	22.5	1.05	0.05	0.015	0.1	2.0
DF70	Hearing-ald Pentode			88D	(16)	0-625	0-025	30	30	0	0.375	0.125	0.22	0.5
DF9I	Variable-mu R.F. Pentode			B7G	(38)	1.4	0-05	90	67-5	۲o.	3.5	1.4	0.9	0.5
DF92	Short Grid Base R.F. Pentode			B7G	(38)	1.4	0.05	90	67-5	〔 17 0	3.7	1.4	0.009 I.0	0.5
ECFI	Variable-mu R.F. Pentode combined (for Triode data see p. 35)	with 7	riode	P.	(143)	6-3	0.2	250	100	2.0	5.0	2.0	2.0	1.6
EF9	Variable mu R.F. Pentode			P.	(47)	6.3	0-2	250	Rg2=	2.5	6.0	1.7	2.2	1.25
EFII	Variable-mu R.F. Pentode			Υ.	(146)	6.3	0-2	250	90 K Ω Rg2=	2.0	6.0	2.0	2.2	2.0
EF12	Short Grid Base R.F. Pentode			Y.	(146)	6-3	0-2	250	75 K Ω 100	2.0	3.0	1.0	2.1	2.0
EF22	Variable-mu R.F. Pentode			88G	(86)	6.3	0-2	250	Rg2= 90 K Ω	2.5	6.0	1.7	2.2	1.2

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VOLTAGE AMPLIFYING PENTODES- continued

TYPE	DESCRIPTION	BASE	VforVh (V)	if or Ih (A)	Va (V)	Vg2 (V)	−VgI (V)	la (mA)	lg2 (mA)	gm (mA/V)	ra (M Ω)
EF36	Short Grid Base R.F. or A.F. Pentode	Octal (72)	6.3	0.2	250	100	2.0	3.0	0-B	I-B	2.5
EF37	Low Microphony A.F. Pentode	Octal (72)	6-3	0.2	250	100	2.0	3.0	0-B	I∙B	2.5
EF37A	Low Microphony, Low Hum A.F. Pentode	Octal (72)	6.3	0.2	250	100	2.0	3.0	0 ·B	I-B	2.5
EF39	Varlable-mu R.F. Pentode	Octal (72)	6.3	0.2	250	Rg2=	∫2.5	6.0	1.7	2.2	-25 > 10
EF40	Low Noise A.F. Pentode	BBA (9B)	6.3	0.2	250	90 K Ω 140	ે 39 2⋅0	3.0	0.55	0·022 I·B5	> 10 f 2·5
EF4I	Variable-mu R.F. Pentode	BBA (96)	6.3	0.2	250	Rg2=	<i>§</i> 2.5	6.0	1.7	2.2	1.0 }
EF42	High Slope R.F. Pentode	BBA (95)	6-3	0.33	250	90 K Ω 250	ે 39 2·0	10	2.3	0.022 9.5	>10 } 0·44
EF50	High Slope R.F. Pentode	B9G (90)	6.3	0.3	250	250	2.0	10	3.0	6.5	1.0
EF54	High 5lope R.F. Pentode	B9G (91)	6.3	0.3	250	250	1.7	10	1.45	7.7	0.5
EF55	High Slope R.F. Pentode for use in Video Amplifiers	B9G (90)	6.3	1.0	250	250	4.5	40	5.5	12	0.055
EF80	High Slope R.F. Pentode	B9A (104)	6.3	0.3	170	170	2.0	10	2.5	7-4	0.4
EF91	High Slope R.F. Pentode	B7G (74)	6.3	0.3	250	250	2.0	10	2.5	7.6	1.0
EF92	Variable-mu R.F. Pentode	B7G (74)	6.3	0.2	250	200	2.5	В-0	2·1	2.5	0.5
EF95	High Slope R.F. Pentode	B7G (147)	6.3	0.175	IB0	120	2.0	7.7	2.4	5-1	0.69
KF3	Variable-mu R.F. Pentode	P. (154)	2.0	0.045	135	135	0.5	2.0	0-6	0.65	1.3
KF35	Variable-mu R.F. Pentode	Octal (6B)	2.0	0.05	120	60	1.5	1.45	0.5	1.0	_
PMI2M	Variable-mu R.F. Tetrode		2.0	0·1B	150	90	0	2.5	0.5	1.4	_
\$P2	Short Grid Base R.F. Pentode	4-pin (4) British 7-pln (24)	2.0	0·1B	135	135	0	3-0	1.0	1.8	0.7

VOLTAGE AMPLIFYING PENTODES-continued

TYPE	DESCRIPTION	1	-	BASE	Vf or Vh (V)	If or Ih (A)	V a (V)	Vg2 (V)	- V gI (V)	la (mA)	lg2 (mA)	gm (mA/V)	ra (MΩ)
SP4	Short Grid Base R.F. Pentode		 	British 5- or 7-pin	4.0	1.0	200	100	2.0	3.0	1.1	2.3	2.2
SP4B	Sharp Cut-off R.F. Pentode		 	(13 or 27) British	4-0	0-65	250	250	2.4	4:0	1.5	3.4	2.0
5P13	Sharp Cut-off R.F. Pentode		 	7-pin (26) P. (47)	13	0.2	200	100	2.0	3.3	1.2	2.2	1.3
SP13C	5harp Cut-off R.F. Pentode		 	British 7-pin (26)	13	0.2	200	200	2-2	2.5	0.9	2.8	2.5
UF9	Variable-mu R.F. Pentode		 	Octal (158)	12-6	0-1	200	Rg2= 60 K Ω	2.5	6.0	1.7	2.2	1.2
UF11	Variable-mu R.F. Pentode		 	Y. (146)	15	0-1	200	Rg2= 70 K Ω	2.0	6.0	1.7	2.2	1.5
UF21	Variable-mu R.F. Pentode		 	88G (86)	12-6	0.1	200	Rg2= 60 K Ω	2.5	6.0	1.7	2.2	1.0
UF4I	Variable-mu R.F. Pentode		 	B8A (96)	12-6	0-1	170	Rg2= 39 K Ω	{2.5 28	6.0	1.75	2·2 0·022	1.0) >10 j
UF42	High Slope R.F. Pentode		 	B8A (95)	21	0.1	170	170	2.0	10	2.8	8.5	0.2
VP2	Variable-mu R.F. Pentode		 		2.0	0.18	135	135	0	3.0	1.25	1.5	0.4
VP2B	Variable-mu R.F. Hexode		 		2.0	0-135	135	60*	1.5	2.0	0.95	1.4	1.3
VP4	Variable-mu R.F. Pentode		 	British 5-	4.0	1.0	200	100	2.0	4.5	1.9	2.3	1.0
VP4A	Variable-mu R.F. Pentode			or 7-pin	4.0	1.2	200	100	2.0	4-25	1.8	2.5	1.4
VP4B	Variable-mu R.F. Pentode				4.0	0-65	250	250	3.0	11.5	4.25	2.0	-
VP13A	Variable-mu R.F. Pentode			7-pin (26) P. (47)	13	0.2	200	100	2.0	4.0	1.4	2.2	-
VP13C	Variable-mu R.F. Pentode			British 7-pin (26)	13	0.2	200	200	2.0	9-0	3.6	2.2	-

VOLTAGE AMPLIFYING PENTODES WITH OIODE(S)

TYPE	DESCRIPTION	BA	ASE	Vfor Vh (V)	If or Ih (A)	(V)	(V)	_Vg1 (V)	la (mA)	lg2 (mA)	gm (mA/V)	ra (M Ω)
OAF9I	Short Grld Base A.F. Pentode with Single Diode	87G	(40)	1.4	0.05	90	90	0	2.7	0.5	0.72	0.5
EAF42	Variable-mu R.F. Pentode with Single Diode	в8А	(93)	6-3	0.2	250	Rg2=	₹2.0	5.0	1.5	2.0	1.4]
E8F2	Variable-mu R.F. Pentode with Double Diode	P.	(140)	6-3	0.2	250	110 K Ω Rg2=	્રે 43 2∙0	5.0	1.6	0.02 1.8	1·3
EBFII	Varlable-mu R.F. Pentode with Double Diode	Υ.	(141)	6-3	0.2	250	95 K Ω Rg2=	2.0	5.0	1.8	1.8	2.0
E8F32	Variable-mu R.F. Pentode with Double Diode	Octal	(75)	6.3	0.2	250	85 K Ω Rg2=	2.0	5.0	1.6	1.8	1.3
EBF80	Variable-mu R.F. Pentode with Oouble	B9A	(103)	6.3	0.3	250	95 K Ω Rg2=	∫ 2 ·0	5.0	1.75	2.2	1.5
UAF42	Variable-mu R.F. Pentode with Single Diode	A88	(93)	12-6	0-1	170	95 K Ω Rg2==	} 41.5 2.0	5.0	1.5	0.022 2.0	>10 {
U8FII	Variable-mu R.F. Pentode with Double Diode	Y.	(141)	20	0-1	200	56 K Ω Rg2=	Ղ 28 2⋅0	5.0	1.7	0.02 1.8	>10 ∫ 1•5
UBF80	Variable-mu R.F. Pentode with Double Diode	B9A	(103)	17	0-1	170	70 K Ω Rg2= 47 K Ω	{2⋅0 26⋅5	5.0	1.75	2·2 0·022	0.9

FREQUENCY CHANGERS

TYPE	DE	SCRII	- 10179	1	ВА	SE	Vfor Vh (V)	If or Ih (A)	Va (V)	Vg2+4 (V)	−VgI (V)	la (mA)	lg2+4 (mA)	gc (mA/V)	ra (K Ω)
AK2	Octode				 Р.	(33)	4.0	0.65	250	70	1.5	1.6	3-8	0.6	1,600
CCH35	Triode Hexa	ode			 Octal	(82)	7.0	0.2	● ∫ 200	(Vg3+5)	(Vg4) 2·0	3.0	(lg3+5) 3⋅0	0.65	900
DK21	Octode				 Octal	(134)	1.4	0.05	△ ₹ 100 1 2 0	Rg5=	0	10	0.25	0.5	8·6 500
DK32	Heptode				 Octal	(77)	1.4	0-05	90	120 K Ω 45 (Vg3+5)	(Vg4) 0 (Vg4)	0.6	(lg5) 0·7 (lg3+5)	0.25	600

Mixer Section.

△ Triode Section.

FREQUENCY CHANGERS-continued

TYPE	DESCRIPTION				BASE		Vfor Vh (V)	If or Ih (A)	V a (V)	Vg2+4 (V)	VgI (V)	la (mA)	lg2+4 (mA)	gc (mA/V)	ra (ΚΩ)
DK40	Octode				B8A	(135)	1.4	0.05	135	Rg5= 270 KΩ	0	1.0	0.25	0.425	1,000
DK9I	Heptode				B7G	(41)	1-4	0.05	90	67.5	(Vg4) 0	I·6	(lg5) 3·2	0.3	600
DK92	Heptode				B7G	(21)	1.4	0.05	90	60 (Vg4)	(Vg3) 0 (Vg3)	0.7	0-15	0.325	650
ECH3	Triode Hexode				Р.	(52)	6-3	0.2	◆ {250 △ {100	100	2.0	3.0 10	3:0	0.65	1,300 8-6
ECHII	Triode Hexode				Y.	(144)	6.3	0.2	● { 250 △ { 150	100	2:0	2:3 15:5	3.0	0.65	1,200 6.0
ECH2I	Triode Heptode				B8G	(88)	6-3	0.33	● {250 △ {100	100	2.0	3.0	6.2	0.75	1·4 6·5
ECH33	Triode Hexode				Octai	(82)	6.3	0.2	● {250 △ {100	100	2.0	3.0	3.0	0.65	1,300 8.6
ECH35	Triode Hexode			٠.	Octal	(82)	6.3	0.3	● {250 △ {100	100	2.0	3.0	3.0	0.65	1,300 8-6
ECH42	Triode Hexode				B8A	(94)	6.3	0.23	● {250 △ {100	85	2.0	3-0 10	3.0	0.75	1,000 B-0
EK2	Octode				Р.	(33)	6-3	0.2	250	50 (Vg3+5)	2 (Vg4)	1.0	0⋅8 (lg3+5)	0.55	2,000
EK32	Octode			• •	Octal	(81)	6.3	0-2	250	50 (Vg3+5)	2 (Vg4)	1.0	0.8 (lg3+5)	0.55	2,000
FC2A	Octode	• •			British 7-pin	(32)	2.0	0.13	135	45 (Vg3+5)	0.5 (Vg4)	0.7	0·7 (lg3+5)	0.27	2,500
FC4	Octode		• •		British 7-pin	(34)	4.0	0.65	250	70 (Vg3+5)	1·5 (Vg4)	1.6	3-8 (lg3+5)	0.6	_
FC13	Octode				P.	(33)	13	0.2	200	70 (Vg3+5)	1.5 (Vg4)	1.6	3·8 (lg3+5)	0-6	-
FCI3C	Octode , ,	• •			British 7-pin	(34)	13	0.2	200	70 (Vg3+5)	1.5 (Vg4)	1.6	3-8 (lg3+5)	0.6	_
KCF30	Triode Pentode				Octal	(170)	2.0	0.2	{	60 (Vg2)	1.5	0·53 5·5	1.0 (lg2)	0.26	 10·5

● Mixer Section. △ Trlode Section.

FREQUENCY CHANGERS-continued

TYPE	DESCRI	PTION	1		ВА	SE	Vfor Vh (V)	If or Ih (A)	V a (V)	Vg2+4 (V)	VgI (V)	la (mA)	lg2+4 (mA)	gc (mA/V)	ra (ΚΩ)
KK2	Octode				Ρ.	(155)	2.0	0-13	135	45 (Vg3+5)	0-5 (Vg4)	0.7	0·7 (lg3+5)	0.27	2,500
KK32	Octode , .	**		• •	Octal	(79)	2.0	0-13	135	45 (Vg3+5)	0.5 (Vg4)	0.7	0.7 (lg3+5)	0-27	_
ТН4В	Triode Heptode	• •			8ritish 7-pin		4.0	1.45	● {250 △ {100	100	2.5	3·25 9·5	6.0	0.75	1,500
TH21C	Triode Hexode				8ritish 7-pin		21	0-2	● { 250 ∧ { 125	70	1·5 0	1.6 6.0	3.8	0.6	_
TH30C	Triode Heptode			• •	British 7-pin		29	0.2	● {250 △ {100	100	2·5 0	3·25 9·5	6.0	0.75	1,500
UCHII	Triode Hexode				Y	(144)	20	0-1	◆ ∫ 200 △ ∫ 150	80	2.0	2.5	3.0	0.75	1,000
UCH21	Triode Heptode				88G	(88)	20	0-1	● ∫ 200	100	2.0	3·5	6.5	0.75	1,000
มี บCH42	Triode Hexode	• •			B8A	(94)	14	0-1	△ \ 100 ● { 170 △ { 100	70	1-85 0	2·1 10	2·6 —	0.67	1,000 8-0

Mixer Section.

 \triangle Triode Section.

DIODES

TYPE	DESCRIPTION	ВА	ASE	Vf or Vh	If or Ih (A)	Va max. (V)	la max. (mA)	
A82	Double Diode	 	V.	(129)	4-0	0-65	200	0.8
DA90	Indirectly-heated Single Diode	 	B7G	(113)	1-4	0.15	330	0.5
EA50	Single Diode	 	B3G	(118)	6-3	0.15	(P.I.V. max.) 50	5.0
EB4	Double Diode with separate Cathodes	 . ,	P.	(139)	6.3	0-2	200	0-8
EB34	Double Diode with separate Cathodes	 	Octal	(58)	6-3	0.2	200	0-8
EB4I	Double Diode with separate Cathodes	 	88A	(92)	6-3	0-3	150	9-0

OIODES—continued

TYPE	DESCRIPTION	BASE	Vf or Vh (V)	If or Ih (A)	Va max. (V)	la max. (mA)
EB9I	Double Diode with separate Cathodes	B7G (37)	6.3	0.3	420 (P.I.V. max.)	9.0
KB2	Double Diode	V. (129)	2.0	0-095	125	0.5
UB4I	Double Diode with separate Cathodes	B8A (92)	19	0-1	150	9.0
2D4A	Double Diode	British 5-pin (8)	4-0	0.65	200	0.8

TRIODES AND DOUBLE TRIODES

TYPE	DESCRIPTION	BASE	Vf or Vh (V)	If or Ih (A)	V a (V) .	_ V g (V)	ta (mA)	μ	gm (mA/V)	ra (ΚΩ)
ACO44	Directly heated Output Triode	British (2)	4.0	1.0	300	38	50	6.0	5.0	1.2
₩ DCC90	R.F. Double Triode suitable for portable transmitters	4-pin (3) B7G (114)	{ 1·4 2·8	0·22 0·11	90	2.5	3.7	15	1.8	8.3
EC31	Low Impedance Triode	Octal (60)	6.3	0.65	250	16	20	10.5	3.2	3.3
EC52	Low power V.H.F. Oscillator Triode	B9G (89)	6.3	0.43	250	2.6	10	60	6.5	9.2
EC53	Low power U.H.F. Oscillator Triode	B3G (120)	6.3	0-25	200	3.3	7.5	33	4.0	I1·4
EC54	Earthed Grid Triode	B9G (15)	6.3	0.43	250	1.5	10	98	9.0	11-1
EC91	Earthed Grid Triode	B7G (59)	6.3	0-3	250	1.5	10	100	8-5	12
ECC31	Medium Impedance Double Triode	Octal (142)	6.3	0.95	250	4.6	6.0	32	2.3	14
ECC32	Medium Impedance Double Triode with separate Cathodes	Ontal (64)	6-3	0.95	250	4.6	6.0	32	2.3	14
ECC33	High Slope, Low Impedance Double Triode with separate Cathodes	O-1 77.45	6-3	0-4	250	4.0	9	35	3.6	9.7
ECC34	Low Impedance Double Triode with separate Cathodes	Ones 1 (64)	6.3	0.95	250	16	10	11.5	2.2	5-2

TRIODES AND DOUBLE TRIODES-continued

TYPE	DESCRIPTION	BASE	Vfor Vh (V)	If or Ih (A)	(V)	- V g (V)	la (mA)	μ	gm (mA/V)	$_{(\mathbf{K}\Omega)}^{\mathbf{ra}}$
ECC35	High-gain Double Triode with separate Cathodes	Octal (64)	6.3	0.4	250	2.5	2.3	68	2.0	34
ECC40	Low Microphony Double Triode with separate Cathodes	B8A (100)	6.3	0.6	250	5.2	6.0	30	2.7	11
ECC81	Double Triode with separate Cathodes for use as Frequency Changer or R.F. Amplifier	B9A (63)	{ 6·3 12·6	0·3 0·15	170	1.5	7.0	57	4.8	12
ECC91	Double Triode for use as a R.F. Amplifier or Oscillator	B7G (80)	6.3	0.45	100	0.85	8-5	38	5.3	7:1
ECFI	Triode combined with R.F. or I.F. Pentode (for Pentode data see page 28)	P. (143)	6.3	0.2	150	3.0	8-0	20	2.2	9.0
ECLII	Triode combined with an Output Tetrode (for Tetrode data see page 37)	Y. (145)	6.3	1.0	250	2:5	2.0	70	2.0	35
ECL80	Triode combined with an Output Pentode (for Pentode data see page 37)	B9A (102)	6.3	0.3	100	2.3	4.0	17-5	1.4	12.5
HL13	Medium împedance Triode	P. (44)	13	0.2	200	3.7	5.0	40	3.3	12
HL13C	Medium Impedance Triode	British 7.pin (19)	13	0.2	200	3.7	5.0	40	3.3	12
PM2A	Output Triode	n	2.0	0.2	135	6.0	5.0	12	2.0	6.0
PM2HL	Medium Impedance Triode	British 4-pin (3)	2.0	0-1	135	1.5	2.2	30	1.4	21.5
PM202	Power Triode	British 4-pin (3)	2.0	0.2	150	14	14	7	3.5	2.0
UCLII	Triode combined with Output Tetrode (for Tetrode data see page 39)	// // //	60	0.1	200	2.0	2.0	65	2.1	30
354V	Medium Impedance Triode	British 5-pin (9)	4.0	0.65	250	4.5	6.5	40	3.5	11.5

TRIODES WITH DIODES

TYPE	DESCRI	NOIT				ВА	SE	Ví or Vh (V)	If or Ih (A)	V a (V)	- V gI (V)	la (mA)	μ	gm (mA/V)	ra (ΚΩ)
ABCI	Double Diode Triode	٠.				P	(45)	4.0	0.65	250	7.0	4.0	27	2:0	13.5
DAC2I	Single Diode Triode					Octal	(132)	1.4	0-025	90	0	0.45	40	0.3	130
DAC32	5ingle Diode Triode					Octal	(65)	1.4	0.05	90	0	0.15	65	0-275	240
EAC91	Single Diode Triode with se	parate (Cathode	for Di	ode	B7G	(36)	6.3	0.3	200	2.8	7.5	36	2.8	12.8
EBC3	Double Diode Triode					P.	(45)	6.3	0.2	250	5.5	5.0	30	2.0	15
EBC33	Double Diode Triode					Octal	(62)	6.3	0.2	250	5-5	5.0	30	2.0	15
EBC4I	Double Diode Triode					B8A	(97)	6.3	0.23	250	3.0	1.0	70	1.3	\$4
КВС1	Double Dlode Triode					P.	(153)	2.0	0.115	135	4.5	2.5	16	1.0	16
KBC32	Double Diode Triode					Octal	(61)	2:0	0.05	100	0	2.4	25	1.2	21
TDD2A	Double Diode Triode				٠.			2.0	0-12	135	1.5	1.95	30	1.2	25
TDD4	Double Diode Triode					5-pin Britisi	ι ` [4.0	0.65	250	7.0	4.0	27	2.0	13.5
TDD13C	Double Diode Triode						n ` [13.0	0.2	200	5.0	4.0	27	2.0	13.5
UBC4I	Double Diode Triode					7-pin B8A	(20) (97)	14.0	0-1	170	1.6	1.5	70	1.65	42

OUTPUT PENTODES

TYPE	DESCRIPTION	BASE	Vf or Vh (V)	If or Ih (A)	Va≔Vg2 (V)	- V gI (V)	la (mA)	Ig2 (mA)	gm (mA/V)	Pout (W)	Ra (ΚΩ)
AL4	Output Pentode (pa max.=9 W)	P. (46)	4.0	1.75	250	6.0	36	40	9.0	4.5	7.0
CL4	Output Pentode (pa max.=9 W)	P. (48)	33-0	0.2	200	8.5	45	6.0	8.0	4.0	4.5
CL33	Output Pentode (pa max.=9 W)	Octal (70)	33.0	0.2	200	8-5	45	6.0	8.0	4.0	4.5

OUTPUT PENTODES—continued

TYPE	DESCRIPTION	ВА	SE	Vfor Vh (V)	If or Ih (A)	$Va=Vg2 \ (V)$	-Vg1 (V)	la (mA)	lg2 (mA)	gm (mA/V)	Pout (W)	Ra (ΚΩ)
DL21	Output Pentode	Octal	(136)	1.4	0.05	120	4-8	5.0	0.9	1:4	0-27	24
DL33	Output Pentode	Octal	(69)	{ i·4 2·8	0·I 0·05	90 9 0	90 90	4·5 4·5	9·5 8·0	1·3	0·27 0·23	8·0
ÐL35	Output Pentode	Octal	(66)	1.4	0.1	90	7.5	7.8	3.5	1.55	0.24	8.0
DL36	Output Pentode	Octal	(66)	1-4	0.1	90	4.5	9.5	1.3	2.2	0.27	8.0
DL41	Output Pentode	B8A	(137)	{ 1·4 2·8	0·1 0·05	90 90	3·6 3·6	8·0 6·0	I∙3 0∙95	2·45 2·2	0·36 0·235	11·3 15
DL66	Hearing-aid Output Pentode	в5А	(121)	1-25	0.015	22.5	1.4	0.3	0.075	0.35	0.0027	75
DL68	Hearing aid Output Pentode	В5А	(121)	1.25	0.025	22.5	2.2	0.6	0.15	0.43	0.005	37-5
DL71	Hearing-ald Output Pentode	B8D	(16)	1.25	0.025	45	1-25	0.6	0.15	0.55	0.0063	100
DL72	Hearing-aid Output Pentode	B8D	(16)	1.25	0.025	45	4.5	1.25	0.4	0.5	0.0195	30
DL92	Output Pentode	B7G	(39)	{1·4 2·8	0·1 0·05	90* 90*	7·0 7·0	7:4 6:1	I-4 I-1	I∙57 I∙42	0·27 0·235	8·0 8·0
DL93	Output Pentode suitable for R.F. or A.F. applications	B7G	(115)	{1·4 2·8	0·2 0·1 }	150†	8-4	13.3	2:2	1.9	0.7‡	8.0
DL94	Output Pentode	B7G	(30)	{1·4 2·8	0·I 0·05	90 90	4·5 4·5	9·5 7·7	2·1 1·7	2·15 2·0	0·27 0·24	10 10
DLL21	Double Output Pentode	Octal	(138)	{1·4 2·8	0·2 0·1	135 135	9·4 9·5	2×8·8 2×8·2	2×2·3 2×2·4	_	1·5 1·5	15§ 15§
ECLII	Output Tetrode (pa max.=9 W) combined with Triode (for Triode data see page 35)	Y.	(145)	6.3	1.0	250	6.0	36	4.0	9.0	3-8	7.0
ECL80	Output Pentode (pa max.=3.5 W) com- bined with Triode (for Triode data see page 35)	B9A	(102)	6.3	0.3	170	6.7	15	2.8	3.2	1.0	li li
EL2		Р,	(48)	6.3	0.2	250	18	32	5.0	2.8	3.6	8.0

^{*} Vg2=67.5 V. † Vg2=90 V. ‡ Pout=1.2 W as R.F. Power Amplifier at 50 Mc/s (intermittent operation).

[§] Ra-a.

OUTPUT PENTODES- continued

TYPE	DESCRIPTION	BASE	Vf or Vh (V)	If or Ih (A)	Va≔Vg2 (V)	- V gI (V)	la (mA)	Ig2 (mA)	gm (mA/V)	Pout (W)	Ra (K Ω)
EL3	Output Pentode (pa max.=9 W)	P. (46)	6.3	0.9	250	6.0	36	4.0	9.0	4.5	7.0
ELII	Output Pentode (pa max.=9 W)	Y. (146)	6-3	0.9	250	6.0	36	4.0	9.0	4.5	7.0
ELI2	Output Pentode (pa max. = 18 W)	Y. (146)	6-3	1.2	250	7.0	72	8.0	15	8.0	3.5
EL31	Output Pentode (pa max.=25 W)	Octal (73)	6-3	1.4	275	9.0	91	11	14	120*	10*
EL32	Output Pentode (pa max.=8 W)	Octal (71)	6-3	0.2	250	18	32	5.0	2.8	3.6	8.0
EL33	Output Pentode (pa max.=9 W)	Octal (70)	6.3	0.9	250	6.0	36	4.0	9.0	4.5	7.0
EL34	Output Pentode (pa max.=25 W)	Octal (149)	6.3	1.5	250	13-5	100	14	11	12	2.0
EL35	Output Pentode (pa max.=18 W)	Octal (70)	6.3	1-35	250	15.5	72	8.0	5.0	6.0	2.5
EL37	Output Pentode (pa max.=25 W)	Octal (70)	6.3	1.4	250	13.5	100	13.5	- 11	69*	3-25*
EL38	Line Time Base Output Pentode (pa max.=25 W)	Octal (73)	6-3	1.4	275	9.0	91	Ш	14	va(pk) 8 k	max,= KV
EL4I	Output Pentode (pa max.=9 W)	B8A (96)	6.3	0.7	250	7.0	36	5⋅2	10	4.2	7.0
EL42	Output Pentode (pa max.=6 W)	B8A (96)	6.3	0.2	2 25	10-5	26	4·1	3.2	2.5	9.0
§ET81	Line Time Base Output Pentode (pa max.=8 W)	B9A (122)	6-3	£-05	250	38-5	32	2.4	4.6	va(pk) 7 i	max.≕ KV
EL91	Output Pentode (pa max,=4 W) ,.	B7G (78)	6.3	0.2	250	12.5	16	2.4	2.6	1.4	16
KL4	Output Pentode	የ. (156)	2.0	0.15	135	5.0	7.0	1.1	2.1	0.44	19
KL35	Output Pentode ,.	Octal (66)	2.0	0.15	135	4.8	5.0	_	2.2	0.31	20
KLL32	Double Output Pentode	Octal (84)	2.0	0.3	120	10-2	3.3	_	2.6‡	0.94	16
PenA4	Output Pentode (pa max,=9 W)	8ritish 7-pin (25)	4.0	1.95	250	5.8	36	5.0	9.5	3.8	8.0
PenB4	Output Pentode (pa max. = 18 W)	British 7-pin (25)	4.0	2-1	250‡	12	72	7.0	8.5	8.8	3.5

^{*} Two valves in push-pull (fixed bias).

[†] gm at Va=Vg2=100 V, Vg1=0 V. ‡ Vg2=275 V.

[§] Provisional information.

OUTPUT PENTODES—continued

TYPE	DESCRIPTION	BASE	Vfor Vh (V)	If or Ih (A)	Va=Vg2 (V)	- V gI	la (mA)	lg2 (mA)	gm (mA/V)	Pout (W)	Ra (K Ω)
Pen4VA	Output Pentode (pa max.=9 W)	British 5- or 7-pin (12 or 25)	4.0	1.35	250	19-5	36	3.0	2.8	3-8	6.0
Pen36C	Output Pentode (pa max.=9 W)	British 7-pln (25)	33	0.2	200	8.5	45	6.0	8.0	4.0	4.5
PL33	Output Pentode (pa max.=9 W)	Octal (70)	19	0.3	225	5.3	32	3-4	9.0	3.3	7.0
PL38	Line Time Base Output Pentode (pa max.= 25 W)	Octal (73)	30	0.3	200	5.5	75	9.0	13.5	va(pk) 8 8	ΚV
PLSI	Line Time Base Output Pentode (pa max.=8 W)	B9A (122)	21.5	0.3	170	22	45	3.0	6-2	va(pk) 7 l	max.= KV
PL82	Output Pentode (pa max.=9 W)	B9A (123)	16-5	0.3	170	10.4	53	10	9.0	4.0	3.0
B PL83	Video Output Pentode (pa max.=9 W)	B9A (105)	15	0.3	170	2.3	36	5.0	10	CRT ca	ok) into ithode= V at i170 V
PM22A	Output Pentode	British 5-pin (II)	2.0	0.15	135	4.5	5.6	-	2.2	0.34	19
PM22D	Output Pentode	British 5-pin (11)	2.0	0.3	135	2.4	5.0	0.8	3.0	0.3	24
PM24A	Output Pentode	British 5-pin (11)	4.0	0.275	300*	22.5	20		1.7	2.8	15
PM24M	Output Pentode (pa max.=7.5 W)	British 5-pin (11)	4.0	14	250	17	30	5.6	3.0	2.8	7.0
QP22B	Double Output Pentode	British 7-pin (35)	2.0	0.3	135	11.7	3.8	0.5	-	1.33	14.7
UCLII	Output Tetrode (pa max.=9 W) combined with Triode (for Triode data see page 35)	Y. (145)	60	0-1	200	8-5	45	6.0	9.0	4.0	4.5
UL4I	Output Pentode (pa max.=9 W)	B8A (96)	45	0.1	170	10.4	53	10	9.5	4.0	3.0

OUTPUT PENTODES WITH DIDDES

TYPE	DESCRIPTION	BAS	SE	V h (V)	Ih (A)	Va≔Vg2 (V)	- V gl	la (mA)	lg2 (mA)	gm (mA/V)	Pout (W)	Ra (KΩ)
ABLI	Double Diode Output Pentode (pa max.=9 W)	۶.	(50)	4.0	2.4	250	6.0	36	4-0	9.0	4.5	7.0
CBLI	Double Diode Output Pentode (pa max.=9 W)	P.	(50)	44	0.2	200	B·5	45	6-0	B-0	4-0	4.5
CBL31	Double Diode Output Pentode (pa max.=9 W)	Octal	(75)	44	0.2	200	B-5	45	6-0	B-0	4-0	4.5
EBLI	Double Diode Output Pentode (pa max.=9 W)	P.	(50)	6.3	1.2	250	6.0	36	5-0	9.5	4.3	7.0
EBL21	Double Diode Output Pentode (pa max.=11 W)	BBG	(B7)	6-3	0-B	250	6.0	36	5-0	9.0	4.5	7.0
EBL31	Double Diode Output Pentode (pa max.= 9 W)	Octal	(75)	6.3	1.2	250	6.0	36	5-0	9.5	4.3	7-0
Pen4DD	Double Diode Output Pentode (pa max.=9 W)	British		4.0	2.25	250	6.0	36	5-0	9.5	4.3	7.0
UBLI	Double Diode Output Pentode (pa max.=11 W)	7-pin Octal	(29) (157)	55	0-1	200	11.5	55	11	B-S	5-2	3.5
UBL2I	Double Diode Output Pentode (pa max.= I i W)	BBG	(B7)	55	0.1	200	13	55	9-5	8.0	4-B	3⋅5

NDNDDE

TYPE	DESCRIPTION	BASE	(V)	Ih (A)		TYPICA	AL OPERATION	
E QB0	Nonode for use as F.M. Detector and Limiter	B9A (I5I)	6-3	0-2	Vb Vg2+g4+g6 Vg5 Vg3 Vg1 Ia Ig2+g4+g6 Ig3 Ig5 ra	170 V 20 V -4 V -4 V 0 V 0 ·2B mA 1·5 mA 0·09 mA 0·03 mA 5·0 M Ω	Vin(g3) r.m.s. Vin(g5) r.m.s. Phase angle bet on g3 and g5 Ra	I2 V I2 V tween signals = 90° 0·33 M Ω

TUNING INDICATORS

DESCRIPTION	BAS	E	Vh (V)	th (A)	(V)	- V g1 (V)	It (mA)	Optimum Load (MΩ)
Tuning Indicator combined with A.F. Pentode	P.	(148)	6.3	0.2	250	2-20	0.65	0.13
<u>-</u>	P.	(150)	6.3	0.2	250	0-5	0-13	2.0
	P.	(51)	6-3	0.2	{250 250	$0-16 \\ 0-5$	0.75	1.0*
	Octal	(76)	6.3	0.2	{250 250	0-16 0-5	0.75	1.0*
Dual Sensitivity Tuning Indicator	Octal	(159)	12:6	0.1	{200 200	0-12·5 0-4·2	1:4	1.0*
Dual Sensitivity Tuning Indicator	Octal	(76)	12.6	0.1	{200 200	0-12·5 0-4·2	1.4	1.0*
	Tuning Indicator combined with A.F. Pentode Tuning Indicator	Tuning Indicator combined with A.F. Pentode P. Tuning Indicator	Tuning Indicator combined with A.F. Pentode P. (148) Tuning Indicator P. (150) Dual Sensitivity Tuning Indicator P. (51) Dual Sensitivity Tuning Indicator Octal (76) Dual Sensitivity Tuning Indicator Octal (159)	DESCRIPTION BASE (V) Tuning Indicator combined with A.F. Pentode P. (148) 6-3 Tuning Indicator P. (150) 6-3 Dual Sensitivity Tuning Indicator P. (51) 6-3 Dual Sensitivity Tuning Indicator Octal (76) 6-3 Dual Sensitivity Tuning Indicator Octal (159) 12-6	DESCRIPTION BASE (V) (A) Tuning Indicator combined with A.F. Pentode P. (148) 6·3 0·2 Tuning Indicator P. (150) 6·3 0·2 Dual Sensitivity Tuning Indicator P. (51) 6·3 0·2 Dual Sensitivity Tuning Indicator Octal (76) 6·3 0·2 Dual Sensitivity Tuning Indicator Octal (76) 6·3 0·2	Tuning Indicator combined with A.F. Pentode P. (148) 6-3 0-2 250	Tuning Indicator combined with A.F. Pentode P. (148) 6·3 0·2 250 2-20	DESCRIPTION BASE (V) (A) (V) (MA) Tuning Indicator combined with A.F. Pentode P. (148) 6·3 0·2 250 2-20 0·65 Tuning Indicator P. (150) 6·3 0·2 250 0-5 0·13 Dual Sensitivity Tuning Indicator P. (51) 6·3 0·2 250 0-16/250 0·75 Dual Sensitivity Tuning Indicator Octal (76) 6·3 0·2 250 0-16/250 0·75 Dual Sensitivity Tuning Indicator Octal (159) 12·6 0·1 200 0-12·5 0-4·2 1·4

RECTIFIERS

TYPE	DESCRIPTION		BAS	SE	Vf or Vh (V)	If or Ih (A)	Va max. (V r.m.s.)	lout max. (mA)
 AZ I	Directly Heated Full Wave Rectifier	 	P.	(43)	4.0	1-1	2×300	100
AZ4	Directly Heated Full Wave Rectifier	 	P.	(43)	4:0	2.3	2×300	200
AZII	Directly Heated Full Wave Rectifier	 	V	(130)	4.0	1-1	2×300	100
	Directly Heated Full Wave Rectifier	 	V	(130)	4:0	2.3	2×300	200
AZ12	Directly Heated Full Wave Rectifier	 		(55)	4.0	1:1	2×300	100
AZ3I			DO A	(131)	4.0	0.72	2×300	70
AZ4I	,			(42)	20	0.2	250	120
CYI	Indirectly Heated Half Wave Rectifier			` '		0.2	250	120
CY31	Indirectly Heated Half Wave Rectifier	 	Octal	(53)	20			
DW2	Directly Heated Full Wave Rectifier	 	British 4	-pin (I)	4.0	1 1.0	2×250	60

^{*} Each Anode.

RECTIFIERS-continued

TYPE	DESCRIPTION	BASE	Vfor Vh (V)	If or th (A)	Va max. (V r.m.s.)	lout max. (mA)
DW4/350	Directly Heated Full Wave Rectifier	British 4-pin (1)	4.0	2.0	2×350	120
DW4/500	Directly Heated Full Wave Rectifier	British 4-pin (1)	4.0	2.0	2×500	120
EY51	Indirectly Heated H.V. Rectifier suitable for C.R.T., E.H.T. supplies			0.09	5,000 lout max.	3·0 = 0·35 mA
EY9I	Indirectly Heated Half Wave Rectifier	B7G (54)	6.3	0.42	250	75
EZ2	Indirectly Heated Full Wave Rectifier	P. (152)	6.3	0.4	2×350	60
EZ35	Indirectly Heated Full Wave Rectifier	Octal (56)	6.3	0.6	2×325	70
EZ40	Indirectly Heated Full Wave Rectifier	B8A (5)	6.3	0.6	2×350	90
EZ4I	Indirectly Heated Full Wave Rectifier	B8A (5)	6.3	0.4	2×250	60
FW4/500	Directly Heated Full Wave Rectifier	British 4-pin (1)	4-0	3.0	2×500	250
FW4/B00	Directly Heated Full Wave Rectifier	British 4-pin (1)	4.0	3-0	2×B50	125
GZ32	Indirectly Heated Full Wave Rectifier	Octal (57)	5-0	2.3	2×300	300
HVR2	Indirectly Heated Half Wave Rectifier	British 4-pin (2)	4-0	0.65	6,000	3-0
HVR2A	Indirectly Heated Half Wave Rectifier	British 4-pin (2)	2.0	1.5	6,000	3-0
IW4/350	Indirectly Heated Full Wave Rectifier	British 4-pln (7)	4-0	2.0	2×350	120
IW4/500	Indirectly Heated Full Wave Rectifier	British 4-pin (7)	4-0	2.5	2×500	120
PY31	Indirectly Heated Half Wave Rectifier	Octal (53)	17	0-3	250	125
PY80	Indirectly Heated Booster Diode for use in Energy Recovery Circuits	B9A (124)		0·3 ax. = 4 KV ax. = 400 mA	la(av) max. = vh-k(pk) max.	
*PY81	Indirectly Heated Booster Diode for use in Energy Recovery Circuits	B9A (185)	7 P.I.V. m	0·3 ax. = 4·5 KV ax. = 450 mA	la(av) max. = vh-k(pk) max.	150 mA

^{*} Provisional Information.

RECTIFIERS—continued

TYPE	DESCRIPTION	BASE	Vh (V)	Ih (A)	Va max. (V r.m.s.)	lout max. (mA)
PY82	Indirectly Heated Half Wave Rectifier	B9A (124)	19	0.3	250	180
PZ30	Indirectly Heated Rectifier with two separate Half Wave Sections, suitable for use as Half					
	Wave or Voltage Doubling Rectifier	Octal (17)	52	0.3	240	200*
URIC	Indirectly Heated Half Wave Rectifier	British 5-pin (6)	20	0.2	250	75
ŲR3C	Indirectly Heated Multiple Rectifier	British 7-pin (18)	30	0.2	2×250	120
UYIN	Indirectly Heated Half Wave Rectifier	Octal (160)	50	0.1	250	140
UYII	Indirectly Heated Half Wave Rectifier	Y. (161)	50	0-1	250	140
UY2	Indirectly Heated Half Wave Rectifier	B8G (85)	50	0.1	250	140
UY4I	Indirectly Heated Half Wave Rectifier	B8A (14)	31	0-1	250	100

VOLTAGE REFERENCE AND STABILIZING TUBES

TYPE	DESCRIPTION	BASE	V Ignition max. (V)	V Burning (V)	I max. (mA)	l min. (mA)	l Quiescent (mA)	A.C. Resistance max. (Ω)
85AI	Neon-filled Voltage Reference Tube	B8G (127)	125	83-87	8.0	1.0	4.5	450
85 A 2	Neon-filled Voltage Reference Tube	B7G (128)	125	83-87	10	1.0	6.0	450
*150B2	Inert-gas-filled Voltage Stabilizer	B7G (186)	180	143-157	15	5.0	10	500
4687	Neon-filled Voltage Stabilizer	P. (49)	130	90~110	40	10	20	250
4687A	Neon-filled Voltage Stabilizer	British 4-pin (23)	130	90-110	40	10	20	250
7475	Neon-filled Voltage Stabilizer	British 4-pin (23)	140	90~110	8	1.0	4.0	300
13201A	Neon-filled Voltage Stabilizer	British 4-pin (23)	135	90~110	200	15	100	80

^{*} Provisional information.

^{*} As voltage doubler Vout = 480 V.

CATHODE RAY TUBES

TYPE	DESCRIPTION	LUMINESCENT COLOUR	PER- SISTENCE	BASE	V h (V)	Ih (A)	MAXIMUM FINAL†	DEFLECTION SENSITIVITY
DB4-I DG4-I DP4-I	13" Electrostatic Oscillograph Tubes for symmetrical operation	Blue Green Blue with Green afterglow	Short Medium Long	B9G (162)	6.3	0.3	1,000	Sx = 0·13 mm/V Sy = 0·21 mm/V
DB4-2 DG4-2 DP4-2	l½" Electrostatic Oscillograph Tubes X plates suitable for asymmetrical operation	Blue Green Blue with Green afterglow	Short Medium Long	B9G (162)	6.3	0.3	1,000	$\begin{array}{l} \text{Sx} = 0.13\text{mm/V} \\ \text{Sy} = 0.21\text{mm/V} \end{array}$
DB7-5 DG7-5 DR7-5	2½" Electrostatic Oscillograph Tubes for symmetrical operation	Blue Green Blue with Green afterglow	Short Medium Long	B9G (162)	6.3	0.3	1,000	Sx = 0·16 mm/V Sy = 0·26 mm/V
DB7-6 DG7-6 DR7-6	2½" Electrostatic Oscillograph Tubes. X plates suitable for asymmetrical operation	Blue Green Blue with Green afterglow	Short Medium Long	B9G (162)	6.3	0.3	1,000	Sx = 0·16 mm/V Sy = 0·26 mm/V
*DB13-2 *DG13-2 *DP13-2	5" Electrostatic Oscillograph Tubes with post-deflection accelera- tor. Suitable for symmetrical operation	Blue Green Blue with Green afterglow	Short Medium Long	B14A (163)	6-3	0.3	2,500 (Va4 max. = 5 KV)	Sx = 0.3 mm/V Sy = 0.35 mm/V (with acceleration
ECR30	3" Electrostatic Oscillograph Tube for symmetrical operation	Green	Medium	B12B (165)	4.0	1.0	1,000	$\begin{array}{c} Sx = 0.21 \text{ mm/V} \\ Sy = 0.21 \text{ mm/V} \end{array}$
ECR35 ECR35P	3½" Electrostatic Oscillograph Tubes for symmetrical or asymmetrical operation	Green Blue with Green aftergiow	Medium Long	B12D (166)	4.0	1.0	2,500	5x = 0.3 mm/V 5y = 0.65 mm/V
ECR60	6" Electrostatic Oscillograph Tube for symmetrical or asymmetrical operation	Green	Medium	B12D (166)	4.0	1.0	2,500	Sx = 0.3 mm/V Sy = 0.575 mm/V

^{*} Provisional information.

[†] Design centre ratings.

TYPE	DESCRIPTION	LUMINESCENT COLOUR	PER- SISTENCE	BASE	Vh (V)	lh (A)	MAXIMUM FINAL† ANODE VOLTAGE	DEFLECTION SENSITIVITY
*MFI3-I	5" Magnetic Radar Tube with metal-backed screen	Orange with Orange afterglow	Long	Octal (176)	6-3	0.3	11,000 (absolute)	0.3 P.cL $\sqrt{\text{Va2}}$ cm./gauss
*MF31-22	I2" Magnetic Radar Tube with metal-backed screen	Orange with Orange afterglow	Long	B12A (116)	6-3	0.3	12,000 (absolute)	Where— P is the distance of
MW6-2	2½" Magnetic Projection Tube with metal- backed screen	White	Medium	(117)	6.3	0.3	25,000	effective centre of the deflector coils from the screen centre.
MW31-16	!2" Magnetic Television Tube incorporating an ion trap and with external conductive coating	White	Medium	B12A (116)	6.3	0.3	9,000	Lis the length in cm. of the elec- tron path through the field of the de-
*MW36-22	14" Rectangular Tele- vision Tube incorpora- ting an ion trap and with external conduc- tive coating	White	Medium	B12A (116)	6-3	0-3	14,000	flector coils. c is a correction factor depending upon the shape of the coils, normally
MW4I-1	16" Metal Cone Tele- vision Tube incorpora- ting an ion trap	White	Medium	B12A (116)	6.3	0.3	14,000	about 0.5.

THYRATRONS

TYPE	DESCRIPTION	BASE	E	V h (V)	Ih (A)	va(pk) max. (KV)	P.I.V. max. (KV)	ia(pk) max. (A)	la max. (A)	VALVE VOLTAGE DROP (V)
EN31	Helium-filled Triode ,	. Octal	(83)	6-3	1-3	I∙0	1.5	0.75	0.01	33
*ME1503	Hydrogen-filled Triode .	. B4D	(175)	6.3	3.75	8.0	8-0	60	0.015	

^{*} Provisional information.

^{*} Provisional information.

[†] Design centre ratings unless otherwise specified.

THYRATRONS—continued

TYPE	DESCRIPTION	BASE	Vf or Vh (V)	If or Ih (A)	va(pk) max. (KV)	P.I.V. max. (KV)	ia(pk) max. (A)	la max. (A)	VALVE VOLTAGE DROP (V)
MTI7	Mercury Vapour Triode	4-pin UX (177)	2.5	5-0	2.5	5.0	2-0	0.5	16
MT57	Mercury Vapour Triode	4-pin UX (178)	5∙0	4.5	1.0	1.0	15	2.5	16
*MT105	Mercury Vapour Tetrode	B4D (179)	5.0	10	2.5	2.5	40	6.4	16
*MT5544	Inert-gas-filled Triode	B4D (180)	2.5	12	1.5	1.5	40	3-2	16
*MT5545	Inert-gas-filled Triode	B4D (180)	2.5	21	1.5	1.5	80	6-4	16
2D2I	Inert-gas-filled miniature Tetrode	B7G (181)	6-3	0.6	0-65	1.3	0.5	0-1	8
1267	Cold Cathode Gas-filled Triode	Octal (184)	Cold C	athode	0-225	_	0-1	0.025	70

^{*} Provisional information.

PLASH-TUBES

TYPE	DESCRIPTION	BASE	MAX. ENERGY OF DISCHARGE (Joules)	ANODE VOLTAGE RANGE (KV)	MIN. TRIGGER VOLTAGE (KV)	APPROX. FLASH DURATION (μ secs.)	PEAK LIGHT OUTPUT (Megalumens)	INTEGRATED LIGHT OUTPUT (Lumen-secs.)
LSD2	Microsecond Flash- Tube	Edison Screw (167)	35	7-10	8	I·0 (peak)	100	1,500
LSD3A	Flash-Tube for port- able equipment	4-pin UX (110) 3-pin. 5amp.(111)	100	2-2-7	4	190	35	3,660
LSD4	Flash-Tube for studio photography	3-pin special (112)	400	2-2-7	4	300	66	26,000

ТҮРЕ	DESCRIPTION	BASE	MAX. ENERGY OF DISCHARGE (Joules)	ANODE VOLTAGE RANGE (KV)	MIN. TRIGGER VOLTAGE (KV)	APPROX. FLASH DURATION (μ secs.)	PEAK LIGHT OUTPUT (Megalumens)	INTEGRATED LIGHT OUTPUT (Lumen-secs.)
LSD5	Flash-Tube for studio set, stage, and com- mercial colour photography	3-pin special (FI2)	1,000	2-2-7	6	500	80	40,000
LSD7	Flash-Tube for studio or portable equip- ment	4-pin U X (110)	200	2-2-7	5	200	44	7,000
*LSD8	Stroboscopic Flash- Tube	4-pin UX (I68)	30W†	2-2-7	4	50	0-06	_
*LSD9	Quartz Flash-Tube for ultraviolet operation	4-pin UX (110)	1,000	2–2·7	4	600	40	25,000
L\$DI0	Flash-Tube for stage, studio set, and colour photography	Wired-in	10,000	2:5-4	17	3,000	250	500,000
LSD12	9" Linear Glass Tube	Wired-in	100	2–2·7	External trigger	80	60	4,500
LSD13	18" Linear Glass Tube	Wired-in	600	2–2-7	required	400	65	27,000
LSD14	24" Linear Glass Tube	Wired-in	2,500	2-2-7	11	1,300	70	150,000
LSD15	12" Linear Glass Tube	Wired-in	200	2-2-7	11	200	50	8,000
LSD16	9" Linear Quartz Tube	Wired-In	500	2-2-7	71	150	140	16,000
LSD17	12" Linear Quartz Tube	Wired-in	1,000	2-2-7	77	500	100	45,000
LSD18	18" Linear Quartz Tube	Wired-in	2,500	2-2-7	11	1,200	43	95,000

^{*} Provisional Information.

[†] Mean power dissipation.

PHOTOCELLS

ТҮРЕ	DESCRIPTION	BASE	MAX. ANODE SUPPLY VOLTAGE (V)	MAX. DARK CURRENT AT MAX. ANODE SUPPLY VOLTAGE (µA)	MAX, CATHODE CURRENT (µA)	SENSITIV- ITY* (µA/Lumen)	MAX. GAS AMPLIFI- CATION FACTOR	PROJECTED CATHODE AREA (sq. cm.)
20AV	Vacuum Photocell with caesium/antimony cathode	B8G (106)	150	0.05	10	45	_	П
20CG	Gas-filled Photocell with caesium/oxidised silver cathode	B8G (107)	90	0.1	5.0	150	10	6.7
20CV	Vacuum Photocell with caesium/oxidised silver cathode	B8G (107)	150	0-05	20	25 (Va=100 V)	_	6.7
52CG	Gas-filled Photocell with caesium/oxidised silver cathode	British 4-pin (125)	90	1.0	3.0	125	10	4.0
55CG	Gas-filled Photocell with caesium/o xidised silver cathode	B3A (American Pee Wee) (126)	90	0.1	2.0	125	10	2.2
57 CV	Photometric Cell with caesium/oxidised silver cathode	British 4-pin (182)	100	(Va=50 V)	0.5	(Va=50 V)	_	4.5
58CG	Gas-filled Photocell with caesium/oxidised silver cathode for end-on incidence of illumination	Wired-in (183)	90	0-1	1.5	100	9	1-1
58CV	Vacuum Photocell with caesium/oxidised silver cathode for end-on incidence of illumination	Wired-in (183)	100	0.05	3.0	(Va=50 V)	_	t-t

^{*} Sensitivity measured at max, anode supply voltage with the whole cathode area illuminated by a lamp of colour temperature 2700° K and with a series resistor of 1 M Ω

PHOTOCELLS—continued

ТҮРЕ	DESCRIPTION	ВА	SE	MAX. ANODE SUPPLY VOLTAGE (V)	MAX. DARK CURRENT AT MAX. ANODE SUPPLY VOLTAGE (μA)	MAX. CATHODE CURRENT (μA)	SENSITIV- ITY* (µA/Lumen)	MAX. GAS AMPLIFI- CATION FACTOR	PROJECTED CATHODE AREA (sq. cm.)
90AG	Gas-filled Photocell with caesium/antimony cathode	B7G	(108)	90	0-1	2.5	150	7	4-0
90AV	Vacuum Photocell with caesium/antimony cathode	B7G	(108)	100	0-05	5-0	45	-	4.0
90CG	Gas-filled Photocell with caesium/oxidised silver cathode	B7G	(109)	90	0-1	2.0	125	10	3⋅1
90CV	Vacuum Photocell with caesium/oxidised silver cathode	B7G	(109)	100	0.05	10	20 (Va=50V)	_	3-1

NOTE.—Caesium/antimony cathode is particularly sensitive to daylight and bluish light.

Caesium/oxidised silver cathode is particularly sensitive to incandescent light and to near infra-red radiation.

IMAGE CONVERTERS

ТҮРЕ	DESCRIPTION	BASE NO.	PHOTO- CATHODE	SENSITIVITY OF PHOTOCATHODE (µA/Lumen)	LUMIN- ESCENT SCREEN	max.	LINEAR MAGNIFI- CATION OF IMAGE	SCREEN RESOLUTION (Lines/cm.)
*MEI200AA	Magnetically focused Image- converter sensitive to day- light and bluish light	171	Caesium/ Antimony	20	Blue Short persistence	6	3-7	200

^{*} Provisional information.

^{*} Sensitivity measured at max, anode supply voltage with the whole cathode area illuminated by a lamp of colour temperature 2700°K and with a series resistor of 1 M Ω .

IMAGE CONVERTERS-continued

ТҮРЕ	DESCRIPTION	BASE NO.	PHOTO- CATHODE	SENSITIVITY OF PHOTOCATHODE (µA/Lumen)	LUMIN- ESCENT SCREEN	Va-k max. (KV)	LINEAR MAGNIFI- CATION OF IMAGE	RESOLUTION
*MEI20IAA	Grid controlled magnetically focused Image-converter sensitive to daylight and bluish light	172	Caeslum/ Antimony	20 For typical operation for extinction of im	Blue Short persistence n, Vg-k = 3 age Vg-k =	ΚV	2:5-3:5	200
*MEI202CA	Magnetically focused Image- converter sensitive to near infra-red radiation	173	Caesium/ oxidised silver	15	Blue short persistence	6	'	200

Variants of these tubes with different photocathodes and luminescent screens are also available, and are distinguished by the last two letters of the type number.

* Provisional information,

U.H.F. VALVES

TYPE	DESCRIPTION	BASE NO.	Vh (V)	Ih (A)	CHARACTERISTICS
MEI00I	Disc Seal Triode for use as a common-grid earthed-anode concentric line oscillator	169	6-3	0.4	$Va = 250 V$ $Vg = -3.5 V$ $Ia = 20 mA$ $\mu = 30$ $gm = 6 mA/V$
*ME1005	Disc Seal Triode for use as a voltage amplifier	169	6.3	0.4	Va = 250 V Vg = -1·3 V Ia = 10 mA μ = 70 gm = 6·5 mA/V

^{*} Provisional Information.

TYPE	DESCRIPTION	BASE NO.	V h (V)	Ih (A)	CHARACTERISTICS
*MEI100	Mechanically Tuned Reflex Kyl- stron for use as a 3 cm. local oscillator	_	6-3	0.6	Frequency Range = 8,500-9,660 Mc/s. Max. resonator voltage = 350 V Max. resonator current = 30 mA Max. reflector voltage = -350 V Min. power output = 20 mW Base:—Octal with coaxial line at pin 4
*MEII0I	3 cm. Fixed Frequency Packaged Magnetron	<u></u>	6-3	0.5	Frequency range = 9,345-9,405 Mc/s. Va max. = 5.7 KV la max. = 7 A pulsed Max. duty cycle = 0.001 Max. pulse length = 2.5 μ sec. Max. power output = 14 KW

ACCELEROMETER TUBE

TYPE	DESCRIPTION	BASE	Vh (V)	ih (A)	CHARACTERISTICS
DDRI00	Accelerometer Double Diode	B8G (164)	6:3	0.6	Va max. = 10 V †Sensitivity = 7.5 mv/g Max. acceleration = 100 g

[†] Across resistance bridge.

ELECTROMETERS

TYPE	DESCRIPTION	BASE	Vf or Vh	If or Ih (A)	V a (V)	lg2 (V)	_VgI (V)	la (μ A)	igi (A)	gm (μ A/V)	μ
ME1400	Electrometer Pentode	Octal (72)	4.5	0-16	△45 ●45	45	2·0 2·0	80 100	<10 ⁻¹¹	240 300	20
*ME1401	Subminiature Electrometer Triode	Wired-in (174)	1-25	0 ·013	9	_	2.5	100	<12.5 × 10 ⁻¹⁴	80	1.7

^{*} Provisional Information.

^{*} Provisional information.

[△] Pentode connected.

Triode connected.

(including obsolete Mullard Valves)

Types morked with asterisk (*) are replacements in AC receivers only. In AC/DC receivers It will be necessory to shunt the heater of the replacement valve, as the heater current of this valve differs from that of the original type,

The data provided on this chart ossumes that the valve to be substituted was being operated under the monufocturer's recommended conditions.

Type Number	Replacement	Type Number	Replacement	Type Number	Replacement
AB1	t	AZ3	†	CBI	t
AC/DD (Hivac)	2D4A	AZ32	l i	CB2	i i
AC/DD (Mazda)	t	AZ33	;	CBC1	i i
AC/DDT	TDD4	AIIB	IW4/350	CC2	HLIŠ
AC/HL	354V	AIIC	1W4/500	CF1	SPI3
AC/HLDD	TD D4	AIID	IW4/350	CF2	VPI3A
AC/HP	SP4	A20B	2D4A	CF3	Ť
AC/PEN	PEN4VA	A23A	TDD4	CF7	SPI3
AC/Q	t	A27D	PEN4DD	CK1	FCI3
AC/Qa	;	A30D	354V	CL6	t t
AC/SG	i	A36A	TH4	CYIC	URIC
AC/SGVM	l i	A36B	TH4B	CY2	l t
AC/SH	i i	A36C	TH4B	CY32	l i
AC/SL	SP4	A40M	l t	CI0B	URIC
AC/SIVM	VP4	A50A	SP4	CI2FM	MW31-16
AC/52	SP4	AS0B	SP4B	C20C	l t
AC/S2PEN	+	A50M	VP4 (7-pin)	C23B	TDD13C
AC/THI	TH4B	A50N	VP4A	C27D	l t
AC/VH	t		(7-pin)	C30B	HLI3C
AC/VP (S-pin)	 	ASOP	VP4B	C36A	TH2IC
AC/VP (7-pin)	VP4A	A70B	PEN4VA	C36C	TH30C
AC/VPB	VP4B		(7-pin)	C50B	SPI3C
AC/VPI	l t	A70C	PENA4	C50N	VP13C
AC/VP2	VP4B	A70D	PENA4	C70D	PEN36C
AC/Y	†	A70E	PENB4	C80B	FCI3C
AC/Z	PENA4	A80A	FC4	DA	†
AC/2DD	t	A430N	354V	DACI	t
AC2/PEN	PENA4	BVA2II `	DW4:2FA	DD4	2D4A
AC2/PENDD	l t	BVA2I4	DW4/350	DD4s	AB2
AC4/PEN	PENB4	BVA2IS	> or	DD6 Cossor	EB91
AF2	l t	BVA2I6 .	IW4/350	Ferranti J	EDYI
AL5	t t	BVA243		DD6	
AL60	†	BVA246	> Ef39	(Tungsram)	t
APP4A	PEN4VA	BVA247		DD6ds	EB4
APP4As	t	BVA264)	DD13	t
APP4B	PENA4	BVA265	>EL33	DD13s	t
APP4Bs	AL4	BVA266	ED3	DD46S	t
APP4E	PENB4	BVA267		DD620	t
APV4	IW4/350	BVA274		DDAI	2D4A
AS4120	SP4	BVA275	ECH35	DDL4	2D4A
AS4125	t	BVA276		DDPP4B	t
AZ2	†	B228	PM2HL	DDPP4Bs	ABLI

[†] No direct replacement available. Please refer to Near Equivalent Guide.

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Type Number Replacement Type Number Replacement Type Number Replacement Type Number Replacement Replacement Type Number Publication Type Number Type Number
DDPP6B † EF2 † HP211c VP2 DDPP6Bs EBLI EF5 EF9 HP215 (Hivac) † DDPP39 † EF6 † HP4101c SP4 DDPP39M † EF8 EF9 HP4105 VP4
DDPP6B † EF2 † HP211c VP2 DDPP6Bs EBLI EF5 EF9 HP215 (Hivac) † DDPP39 † EF6 † HP4101c SP4 DDPP39M † EF8 EF9 HP4105 VP4
DDPP6Bs EBLI EF5 EF9 HP2I5 (Hivac) † DDPP39 † EF6 † HP4I0Ic SP4 DDPP39M † EF8 EF9 HP4I05 VP4
DDPP39 † EF6 † HP4101c SP4 DDPP39M † EF8 EF9 HP4105 VP4
DDPP39M † EF8 EF9 HP4105 VP4
DDT † EK3 † HP4115c (5-pin) †
DDT2 TDD2A EL3N EL3 HP4115c (7-pin) VP4A
DDT4 TDD4 EL5 † HR210 PM2HL
DDT4s ABCI EL6 + H2 PM2HL
DDT6s EBC3 EL36 + H2D TDD2A
DDTI3 TDDI3C EZI † H4D †
DDT13s
DDT220 TDD2A FGI7 MTJ7 IW4 IW4/500
DET22 MEI001 FG57 MT57 KT2 PM22A
1 11111
DH63M EBC33* G470 DW2 KT61 †
DH142 UBC41 G2080 (5-pin) URIC KT63 †
DH147 EBC33 G2080 (P base) CYI KT66 EL37
DHI50 EBC4I G4I20 DW4/500 KTW6I †
DKI † G4120N IW4/500 KTW6IM †
DL2 † HAD † KTW63 †
DL63 EBC33* HD14 DAC32 KTZ63 †
DL91 † HD22 TDD2A K23B TDD2A
DN4I † HD23 TDD2A K30A PM2HL
DN143 EBL21 HD24 TDD2A K30B †
DO42 PEN4DD HL2 PM2HL K30C PM2HL
DP61 EF95 HL2K PM2HL K30D PM2HL
DP495 PEN4DD HL4+ 354V K30G PM2A
DP4480 † HL4g † K30K PM2HL
DT41 TDD4 HL4gs † K40B †
DT436 TDD4 HLI3 HLI3C K40N PMI2M
DTI336 (7-pin) TDDI3C (Tungsram) K50M VP2
DTUI TDDI3C HLI3 (Hivac) † K50N VP2B
DW3 DW4/350 HL13s HL13 K70B PM22A
DW4 DW4/500 HL21DD TDD2A K70D PM22D
D4 354V HL22 † K77B QP22B
D41 2D4A HL23DD † K80A FC2
D63 EB34* HL4I † K80B FC2A
D77 EB91 HL4IDD † K435/10 ACO44
D152 EB91 HL133DD † LD210 †
D400 2D4A HL210 PM2HL LL2 PM2HL
D1300 † HLA2 354V LL2s †
EAF4I † HLBI † LNI52 ECL80
EC50 † HL/DD1320 † LP2 (Osram) PM2A
EC55 ME1001 HP13 † LP2 (Ferranti) PM202
ECH2 † HPI3s VPI3A LP4 ACO44
ECH4 † HP210nc (7-pin) SP2 LP220 PM2A

[•] See note at beginning of section. † No direct replacement available. Please refer to Near Equivalent Guide.

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Type Number	Replacement	Type Number	Replacement	Type Number	Replacement
L2 (Ferranti)	PM2A	OM5	EF36	PP6BG	EL33
L2 (Mazda)	PM2ML	OM5A	EF37	PP6Bs	EL3
L2/B	PM2ML	OM5B	EF37A	PP34	Ť
L2/DD	†	OM6	EF39	PP34s	CL4
L21	PM2ML	OM7	EF39	PP35	PEN36C
L21/DD	TDD2A	OM9	EL32	PP36	Ť
L210	PM2ML	OMI0	ECM35*	PP220	PM 202
ME6s	EMI	OP41	PENB4	PP3/250	ACO44
MH4	354V	OP42	PENA4	PT2	PM22A
MHD4	†	O202	FC2	PT4 Marconi	D140414
MHL4	+	O406	FC4	P14 Osram	PM24M
MKT4	PEN4VA	O1307 (P base)	FCI3	PT4 (Ferranti)	PENA4
MM4V	ŧ	O1307 (7-pin)	FCI3C	PT4D	†
MP4106c	VP4	PBI	PM2A	PT4I	PM24M
MP/PEN	PEN4VA	PEN4V	t	PTZ	i t
MPT4	PEN4VA	PEN4VB	PENA4	PV4	DW4/350
M54B	SP4	PEN24	†	PV29s	Ť
MS4C	SP4	PEN25	†	PV30	UR3C
MSG/HA	SP4	PEN26	† †	PV30s	†
M5G/LA	SP4	PEN40DD	Ť	PV495	DW2
M5P4	SP4	PEN220	PM22A	PV4200	DW4/500
MS/PEN	SP4	PEN230	†	PVB6s	Ť
M5/PENA	SP4	PEN231	PM22D	PX4	ACO44
MU12	IW4/350	PEN 3520	PEN36C	PX230	PM202
MU12/14	IW4/500	PENAI	PM24M	P2	PM202
MUI4	IW4/500	PENBI	PM22A	P12/250	ACO44
MV/\$G	Ť	PENDD4020	†	P220	†
MVS/PEN	†	PL17	MTI7	(Tungsram)	
(5-pin)		PL21	2D2I	P220 Mazda	PM2A
MV5/PEN	VP4A	PL57	MT57	(Hivac)	D14000
(7-pin)	_	PL105	MT105	P220A	PM 202
MV5/PENB	†	PL1267	1267	P225 (5-pin)	PM22A
N14	DL35	PMIA	PM2ML	P240	PM202
N15	†	PMIHF	PM2ML	P435	PM24M
N16	DL33	PMIHL	PM2ML	P440N P441N	PEN4VA
NI7	DL92	PMILF	†	P495	PENA4
N19	DL94	PM2	† PM2ML	OP230	QP22B
N40	PENA4	PM2DL PM2DX	PM2ML	QP240 (Mazda)	
N41	1 -	PM12		QP240 (Hivac)	
N63	† EL37	PM12A	†	QPT2	j .
N66 N77	EL9I	PM22	†	Q583/3	85A2
N142	UL4I	PM24	†	RV120/350	DW4/350
N144	EL9I	PM24B	†	RV120/350s	AZI
N147	EL33	PM24C	†	RV120/500	DW4/500
N150	EL4I	PM252	†	RV120/500s	†
N151	EL42	PP2	PM22A	RV200/600	FW4/800
N152	PL81	PP2s	KL4	RZ	URIC
OM1	CY3I	PP4	PM24M	RI	DW2
OM3	EB34	PP4s	†	R2	IW4/350
OM4	EBC33	PP6As	EL2	R3	IW4/500

^{*} See note of beginning of section. † No direct replacement available. Please refer to Near Equivolent Guide.

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Type Number	Replacement	Type Number	Replacement	Type Number	Replacement
R4	DW4/350	51324	†	U84	t
R4A	DW4/500	51328	SPI3	UIOI	l t
RI2	EY5I	TDD2	t	U142	UY4I
R14	PZ30	TDD13	Ť	U143	AZ3I
R41	DW4/500	TH4	l i	U145	UY4I
R42	IW4/350	TH4A	TH4B	U147	EZ35
R52	GZ32	TH22C	TH30C	U149	Ť
SD2	PM2HL	TH29	TH30C	U 50	EZ40
SE211c	PMI2M	TH30	TH30C	UISI	EY51
SG215	PM12M	TH41	t	U152	PYB0
5G215A	PM12M	TH62	i i	U201	CY3I
5P4 (Tungsram)		TH233	t	U403	t
5P4C	i	TH2321	TH30C	U404	UY4I
5P4s	AF7	TP2S	t	U4020	†
5P6	EF91	TT4	Ė	VHT2	FC2
5P6s	†	TV4	l i	VHT2A	FC2A
5P13	i i	TV6	EMI	VHT4	FC4
(Tungsram)	1	TX4	t	VHTA	t
5PI3B	SPI3C	TX2I	тнаіс	VM4V	i i
5P13s	SPI3	TX4I	TH4B	VMP4	VP4
5P22	t	T4I (Ekco)	354V	VMP4G	t t
5P2 0	SP2	UAF4I	t	VM54	t
5P215	† †	UCH4	l i	VMS4B	i i
5P220	PM202	UCH41	l i	VO2	FC2A
5P1320	SPI3C	UD2	PM202	VO2s	KK2
5PT2	SP2	URI	CYI	VO4	FC4
5PT4A	SP4 (7-pln)	UR2	†	VO4s	AK2
SS210	Ť	UR3	i i	VO6s	EK2
SU6I	EY51	UU3	IW4/350	VO13	FC13C
S4V	SP4	UU4	IW4/350	VOI3s	FC13
S4VA	SP4	UU5	IW4/500	VP4C	t t
54VB	SP4	UU6	t	VP6	EF92
511A	DW2	UU8	+	VPI3	i t
511D	DW4/350	UU9	EZ40	VPI3B	VPI3C
521	l i	UU60/250	IW4/350	VP22	†
522	l i	UU120/350	DW4/350	VP4I (Mazda)	†
523	l i	UU120/350A	TW4/350	VP4I (Ekco)	VP4B
524	l į	UU120/500	DW4/500	VPI33	†
530C	ACO44	(Mazda)		VP2I0	t
530D	t	UU120/500	1W4/500	VP215	†
\$213	PM I2M	(Hivac)		VPI321	†
\$215	t	UY3I	†	VP1322	VPI3C
521SA	Ì	UIO	DW2	VPT2	†
5215B	Ť	U12/13	DW4/350	VPT4	VP4 (5-pin
5215VM	PM12M	U14	DW4/500	VPT4B	VP4A
5217	VP2	U1B/20 {	FW4/500	VPUI	VPI3C
5218	SP2	316/20 S	FW4/800	V52	PMI2M
5420	VP4B	U3I	PY3I	V524	PMI2M
5434N (5-pin)	t	U50	†	VS24K	PM I2M
5434N (7-pin)	VP4A	U70	EZ35	V5210	PM I2M
(אוק-ז) אודנדנ	41444	U82		V\$215	PM12M

[†] No direct replacement available. Please refer to Near Equivalent Guide.

Type Number	Rep!acement	Type Number	Replacement	Type Number	Replacement
VX2	VP2B	IA7VG	DK32	4D1	ţ
VX2s	† IAC6		DK92	4G/280K	2D21
VX32	MEI401	IC1 (Mazda)	DK91	4THA	t
V20	URIC	IC5G	DL35	4XP	ACC44
V20s	CYI	IC5GT/G	DL35	4/100BU	FW4/500
V30	Ť	IC6		5CPI-A	DG13-2
WD142	UAF42	IC7G	† †	5CP7-A	DP13-2
WD150	EAF42	IDS	†	5FP7-A	MFI3-I
W17	DF9I	ID6	†	5V4G	GZ32
W2I	†	ID7G	, , , , , , , , , , , , , , , , , , ,	5Y3G	†
W42	i i	IDI3	DA90	5Y4G	†
W63	i i	IE5G	†	5Z4G	GZ32
W77	EF92	IF2	DF92	6A6	
W142	UF4I	1F3	DF9I	6A7	† †
W143	EF22	IF4	†	6A7E	1 1
W147	EF39	IF5G	KL35	6A8G	†
W150	EF4I	IFD9	DAF9I	6A8GT	† †
X14	DK32	TH5G	DAC32	6AB8	ECL80
XI7	DK91	TH5GT/G	DAC32	6AG6G	EL33
X21	FC2	TH6G		6AK5	EF95
X22	FC2	IL4	† DF92	6AK6	
X42	†	ILA6		6AL5	† E891
X61M	ECH35	ILC5	†	6AM5	
X65		ILD5	1 1		EL9I
X142	† UCH42	IEH4	1	6AM6	EF91
X143	ECH21	ILN5	† † †	6AT6 6BD6	į į
X147	ECH35	1N5G	Ť	6BE7	† EQ80
X150	ECH42	INSGT/G	DF33	6BT6	
YD2	†	IN5VG	DF33	6BX6	† EF80
Y61	, †	IPIO	DL92	6C6	
Y62	†	IPII	DL94	6C10	† ECH42
Y63	↓ ÷	IQ5GT	DL36	6CJ6	EL8I
Y220	† †	IR5	DK9I	6DI (Mazda)	
ZDI7	DAF9I	154	†	6D2	EA50 EB91
ZD152	EBF80	155	DAF91	6D6	
ZI4	DF33	IT4	DF91	6E8G	t ECH35
Z2I	†	IU5		6F12	EF91
Z22	SP2	2D4	†	6F16	EF4I
Z77	EF91	2D13	† † †	6H6GT	EB34*
Z90	EF50	2DI3A	l ÷	6]6	ECC91
Z 142	UF42	2D13C		*	
Z150	EF42	2D21	2D21	6J7G	† EF37A*
Z152	EF80	2]42	MEI IOI	6J7GT 6J8G	
0A4G	1267	3A4	DL93	*	† +
0E3	85AI	3A5	DCC90	6K7G	† EF39*
IA3	DA90	3NP4	MW6-2	6K7GT 6K8G	1
IA4E		3Q4		6K8GT	†
IA4P	† †	3Q5GT/G	† DL33		† †
IA7G	Ť	384	DL33	6L6G 6L34	EC91
		001	J-74	ULJT	E-071

^{*} See note at beginning of section. † No direct replacement available. Please refer to Near Equivalent Guide.

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Type Number	Replacement	Type Number	Replacement	Type Number	Replacement
6N7GT/G	ţ	16A5	PL82	2105PG	FC2
6N8	EBF80	17Z3	PY8I	2105PT	i t
6P8G	ECH35*	19X3	PY80	210VPT (4-pin)	l i
6P28	†	19Y3	PY82	210VPT (7-pin)	i i
6Q7G	Ť	20A1	ТН4В	215P ` ´	İ
6Q7GT	Ť	20A3	2D2I	2155G	PMI2M
657	EF39*	21A6	PL8I	220HPT	PM22A
657G	t t	25RE	t t	220/OT	PM22A
65C7	l t	25Y5	†	220P	t t
65]7	†	25Z4G	†	220PA	PM2A
6SK7	†	25Z5	†	2205G	t
6SL7GT	ECC35*	25Z6G	†	220V5	PMI2M
65N7GT	†	35RE	†	220V\$G	PMI2M
6U5/6G5	†	36	†	230PT	†
6U7G	l †	39/44	t t	230XP	†
6V6G	†	40SUA	†	240QP	QP22B
6W7G	l t	41E	†	244V	354V
6X2	EY51	41/MHF	354V	302THA	TH30C
6X5G	EZ35	41/MHL	354V	332PEN	CL33
6X5GT/G	EZ35	41/MPG	FC4	408BU	DW2
6ZY5G	†	41/MPL	354V	442BU	DW4/350
7A2	PEN4VA	41/M5G	SP4	460BU	DW4/500
7A3	PENA4	41/MTL	354V	484V	†
7A7	†	415TH	†	506BU	DW2
7B7	†	42/42E	†	723A/B	MEII00
7C5	†	42MP/PEN	PENA4	927	55CG
7D6	PEN36C	42/OT	PENA4	1267	1267
7D9	EL91	43IU	IW4/350	1561	DW4/500
7F7	†	44IU	IW4/500	1821	DW2
7K7	†	45IU	†	1861	IW4/500
757	†	54KU	GZ32	1867	IW4/350
7Y4	†	62DDT	EBC4I	1877	HVR2
8AI	SP4	62TH	ECH42	1881	IW4/350
8D2	†	62VP	EF4I	2101	t
8D3	EF91	635PT	EF50	2102	†
9A1	VP4	64ME	EM34	4065	ME1401
9D2	†	66KU	EZ40	5544	MT5544
9D6	EF92	67PT	EL4I	5545	MT5545
IODI	†	77/77E	†	5557	MT17
IIA2	†	78/78E	†	5559	MT57
I2AT7	ECC81	80	†	5802	MEI40I
I2XP4	MW31-16	84/6Z4	†	5861	ME1001
12Z3	†	121K	MW31-16	55035	MEII01
13PGA	†	202DDT	TDD13C		
135PA	†	2025TH	TH2IC		
13VPA	†	2I0DDT	TDD2A		
15	j +	2I0DET	PM2HL		
15A2	t	210HF	PM2HL		
15A6	PL83	210LF	†		
ISDI	t	210PG	FC2		

^{*}See note at beginning of section. † No direct replacement available. Please refer to Near Equivalent Guide.

Type Number	BASE	Mullard Replace- ment	BASE	CONVERSION
ABI	0	2D4A	0	No circuit change. 2D4A has no top cap.
AC/DD (Mazda)	ō	2D4A	ō	No circuit change. 2D4A has no top cap.
AC/Q	M	PENB4	М	Bias may require adjustment.
AC/Qa	K	EL37	К	Bias may require adjustment.
AC/SG	O/M	SP4	O/M	Raise Vg2 to 100V for R.F. amplifier.
AC/SGYM	O/M	VP4	0/м	Raise Vg2 to 100V for R.F. amplifler.
AC/SH	M	SP4	M	Bias may require adjustment.
AC/S2PEN	М	SP4	м	Bias may require adjustment.
AC/VH	0	VP4	0	Bias may require adjustment.
AC/VP (5-pin)	0	VP4A	м	Change base.
AC/VPI	M	VP4B	М	Rewire base.
AC/Y	O/M	PEN4VA	O/M	Bias may require adjustment.
AC/2DD	М	PEN4DD	Ìм	Interchange connections to pins 2 and 6.
AC2/PENDD	М	PEN4DD	М	Rewire base.
AF2	0	VP4A	М	Change base.
AL5	P	PENB4	М	Change base.
AL60	M	PENB4	М	Rewire base. Change Rk to 175Ω.
APP4As	P	PEN4VA	O/M	Change base.
AS4125	o	VP4	Ó	Volume control will be less gradual in operation.
AZ2	Р	FW4/500	A	Change base.
AZ3	Р	IW4/350	Α	Change base.
AZ32	K	FW4/500	Α	Change base.
AZ33	K	IW4/350	A	Change base.
A40M	0	VP4	0	Volume control will be less gradual in operation.
CB1 CB2	\ \ \ \	EB34	К	Change base. When rewiring connect separate cathodes of EB34 together. EB34: Vh=6·3V.
CBCI	P	TDD13C	M	Change base.
CF3	P	VPI3C	M	Raise Vg2 to Va.
CL6	P	CL4	P	Change Rk to 170 Ω. Raise Vg2 to 200V
CY2	P	UR3C	M	Change base.
CY32	K	UR3C	М	Change base.
C20C	0	EB34	К	Change base. When rewiring connect separate cathodes of EB34 together. EB34: Vh=6·3V.
C27D	М	CBL31	K	Change base.
DA	М	HL13C	М	Bias may require adjustment.
DACI	Р	DAC32	К	Change base.

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Type Number	BASE	Mullard Replace-	BASE	CONVERSION
		ment		
DD6 (Tungsram)	0	EB34	К	Change base.
DDI3 DDI3s	°}	EB34	К	Change base. When rewiring connect separate cathodes of EB34 together. EB34: Vh=6.3V.
DD465	0	2D4A	0	Rewire base.
DD620	0	EB34	K	Change base.
DDPP4B	М	PEN4DD	M	Rewire base.
DDPP6B	М	EBL31	K	Change base,
D DPP39	М	CBL3I	K	Change base.
DDPP39M	М	CBL31	K	Change base.
DDT	M	TDD4	M	Bias may require adjustment.
DDT13s	P	TDD13C	M	Change base.
DDT215	0	TDD2A	0	Bias may require adjustment.
DF1	P	DF33	K	Change base.
DH63	K	EBC33*	K	Earth pin I.
DKI	P	DK32	K	Change base.
DL2	Р	DL35	K	Change base.
DL91	B7G	DL92	B7G	Rewire base so that Vf is between pin 5 and pins 1 and 7 connected together.
DN4I	М	PEN4DD	М	Rewire base. Raise Vg2 to Va. Increase Rk to I40 Ω .
DP44B0	M	CBL31	K	Change base.
D1300	₽	EB34	K	Change base. When rewiring connect separate cathodes of EB34 together. EB34: Vh=6·3V.
EAF4I	BBA	EAF42	BBA	Connect pins 4 and 7 together.
EC50	Р	EN3I	K	Change base.
ECH2	Р	ECH3	P	ECH3: lh=0.3A,
ECH4	P	ECH2I	BBG	Change base.
ECH4I	BBA	ECH42	BBA	Screen grid resistors may need alteration.
EF2	Р	EF9	P	Bias may require adjustment.
EF6	P	EF36	K	Change base,
EK3	Р	EK2	P	Raise Vg2 to 200V. EK2: $lh=0.2A$,
EL5	Р	EL35	K	EL35 : Vg2=250V max. Change Rk to IB0 Ω . Change base.
EL6	P	EL35	K	EL35 : Vg2=250V max. Change Rk to IB0 Ω . Change base.
EL36	K	EL35	K	EL35 : Vg2=250V max. Change Rk to IB0 Ω .
EZI	Р	EZ35	K	Change base. EZ35: lh=0.6A.
HAD	М	TDD13C	М	Blas may require adjustment.
HL4g	М	354 V	0	Change base.
HL4gs	Р	354 V	0	Change base.
HL13 (Hivac)	М	HLI3C	М	Shunt heater with 130 Ω , 2W resistor,
HL22	МО	PM2HL	Α	Change base.
HL23DD	МО	KBC32	K	Change base.

Type Number	BASE	Mullard Replace-	BASE	CONVERSION
••		ment		
HL4I	MO	354V	0	Change base.
HL41DD	MO	TDD4	M	Change base.
HLI33DD	MO	TDD13C	M	Change base.
HLBI	Α	PM2HL	A	Bias may require adjustment.
HL/DD1320	М	TDDI3C	M	Bias may require adjustment.
HP13	М	VP13A	P	Change base.
HP210nc (4-pin)	Α	SP2	M	Change base.
HP215 (Hivac)	М	SP2	M	Raise Vg2 to Va.
HP4115c (5-pin)	0	VP4A	M	Change base.
H4D	М	TDD4	M	Bias may require adjustment.
KT4!	М	PENA4	M	Bias may require adjustment.
KT61	K	EL33	K	Bias may require adjustment.
KT63	K	EL32	K	Rewire base.
KTW61	K	EF39*	K	Earth pin 1. Bias may require adjustment.
KTW6IM	К	EF39*	K	Bias may require adjustment.
KTW63	κ	EF39*	K	Earth pin 1.
KTZ63	K	EF37A*	K	Connect pin 5 to pin 8.
K30B	Α	PM2HL	A	Change VgI to -1.5V.
K40B	Α	PMI2M	A	Raise Vg2 to 90V.
LD210	Α	PM2HL	A	Bias may require adjustment.
LL2s	Р	PM2HL	A	Change base.
L2/DD	0	TDD2A	0	Change Vg1 to -1.5V. Not suitable as Class B driver.
MHD4	М	TDD4	M	Bias may require adjustment.
MHL4	0	354V	0	Bias may require adjustment.
MM4V	0	VP4	0	Volume control less gradual in operation.
MV/SG	0	VP4	O/M	Bias may require adjustment.
MVS/PEN	0	VP4A	M	Change base.
(5-pin) MVS/PENB	м	VP4B	М	Raise Vg2 to Va.
N15	к	DL33	k	Increase bias.
N40	Ô	PEN4VA	O/M	Bias may require adjustment.
N63	ĸ	EL32	K	Rewire base.
PEN4V	0	PEN4VA	o	Change VgI to —22V. No change with automatic bias.
PEN24	МО	KL35	к	Change base. Change Vgl to -4.5V.
PEN25	MO	KL35	ĸ	Change base.
PEN26	Р	CL4	P	Change Rk to 170 Ω. CL4 : Vg2=200V.
PEN40DD	М	CBL31	K	Change base.
PEN230	A/O	PM22A	A/O	Change VgI to $-4.5V$ at Va=Vg2=I35V and Ra to approximately 19K Ω .
PENDD4020	М	CBL31	K	Change base.
PMILE	Α	PM2HL	A	Change Vg I to — I·5V.
PM2	Α	PM2A	A	Change VgI to -6V.
PM12	Α	PM12M	Α	Raise Vg2 to 90V.

^{*}See note at beginning of Direct Replacement Guide.

Type Number	BASE	Mullard Replace- ment	BASE	CONVERSION
PMI2A	Α	PMI2M	Α	Raise Vg2 to 90V.
PM22	A/O	PM22A	A/O	Change VgI to -4-5V at Va=Vg2=135V and Ra to approximately I9K().
PM24	A/O	PM24A	0	Change base, if necessary.
PM24B	0	PM24M	0	Redesign circuit. PM24M: Va=Vg2= 250V max.
PM24C	0	PM24M	0	Redesign circuit. PM24M: Va=Vg2= 250V max.
PM252	Α	PM2A	Α	Change VgI to -6V. Ra=7KΩ.
PP4s	Р	PM24M	0	Change base.
PP34	М	PEN36C	М	Connect gl to T.C.
PP36	М	PEN36C	м	Rewlre base.
PT4D	М	PEN4DD	м	Rewire base.
PTZ	М	PEN36C	м	Rewire base.
PV29s	Р	UR3C	M	Change base.
PV30s	Р	UR3C	M	Change base.
PVB6s	Р	EZ35	К	Change base. Check Ih when series heated.
P220 (Tungsram)	Α	PM202	A	Bias may require adjustment.
QP240 (Mazda)	9-pin	QP22B	М	Change base.
QP240 (HIvac)	M	QP22B	M	Bias may require adjustment.
QPT2	М	QP22B	M	Bias may require adjustment.
RV120/500s	Р	DW4/500	A	Change base.
SP4 (Tungsram)	М	SP4	M	Rewire base.
SP4C	P	SP4B	M M	Change base.
SP6s	Р	EF37A	ĸ	Change base.
SP13	M	SPI3	P	Change base.
(Tungsram) SP22	MO	SP2	М	Change base.
SP215	М	SP2	M	Bias may require adjustment.
SS210	Α	PMI2M	Α	Raise Vg2 to 90V.
S21	Α	PM I2M	Α	Raise Vg2 to 90V.
\$22	Α	PM I2M	Α	Raise Vg2 to 90V.
S23	Α	PM I2M	Α	Raise Vg2 to 90V.
S24	Α	PM12M	Α	Raise Vg2 to 90V.
\$30D	Α	ACO44	Α	Change Vf to 4V.
S215	Α	PMI2M	Α	Raise Vg2 to 90V.
\$215A	Α	PMI2M	Α	Raise Vg2 to 90V.
S215B	Α	PMI2M	Α	Raise Vg2 to 90V.
S434N (5-pin)	0	VP4A	м	Change base.
S1324	M	SP13C	M	Raise Vg2 to Va.
TDD2	0	TDD2A	0	Change Vg1 to -1.5 V. Not suitable as Class B driver.
TDD13	Р	TDD13C	М	Change base.
TH4	М	ТН4В	М	Change Rk to 140 Ω . Grid leak to be increased to 50K Ω between grid and cathode.

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Type Number	8ASE	Mullard Replace- ment	8ASE	CONVERSION
TH4I	мо	ТН4В	М	Change base. Receiver may require re-
TH62	к	{CCH35}	K	For AC/DC receivers—CCH35. For AC receivers—ECH35.
TH233	МО	TH30C	М	Change base. Receiver may require re- aligning.
TP25	MO	KCF30	K	Change base.
TT4	0	EC31	K	Change base. Raise Vh to 6-3V.
TV4	P	EM1	P	Raise Vh to 6·3V.
TX4	М	ТН4В	M	Change Rk to 140 Ω . Grid leak to be increased to 50K Ω between grld and cathode.
UAF4I	88A	UAF42	88A	Connect pins 4 and 7 together.
UCH4	k	UCH2I	88G	Change base.
UCH41	88A	UCH42	B8A	Screen grid resistor may need alteration.
UR2	P	UR3C	M	Change base.
UR3	P	UR3C	M	Change base.
UU6	МО	IW4/350	A	Change base.
UU8	MO	GZ32	K	Change base. GZ32, Vh=5V.
UY31	K	UY2I	88G	Change base.
U50	K	GZ32	K	GZ32 has indirectly heated cathode.
U82	88G	EZ35	K	Change base.
U84	B8G	AZ3I	K	Change base.
UIOI	88G	UY2I	88G	Join pins 2, 4 and 6 together.
U149	88G	EZ 35	K	Change base.
U403	MO	CY3I	K	Change base. Check Ih=0.2A.
U4020	0	URIC	0	Check Ih=0:2A.
VHTA	M	FCI3C	M	Vg2 max.=90V. Receiver may require realigning.
VM4V	0	VP4	0	Volume control less gradual in operation.
VMP4G	M	VP4A	M	Bias may require adjustment.
VMS4	0	VP4	0	Volume control will be less gradual in operation.
VMS48	0	VP4	0	Volume control will be less gradual in operation.
VP4C	M	VP4B	M	Rewire base.
VPI3	M	VPI3A	P	Change base.
VP22	MO	KF35	K	Change base.
VP41 (Mazda)	MO	VP4B	M	Change base.
VP 33	MO	VPI3C	M	Change base. Bias may require adjust- ment.
VP210	M	KF35	K	Change base.
VP215	M	VP2	M	Increase Vg2 to Va.
VP132I	M	VPI3C	M	Change base connections.
VPT2	M	VP2	M	Increase Vg2 to Va.
VX2s	P	VP2B	M	Change base.
∀30	0	URIC	0	Check Ih=0.2A.

Type Number	BASE	Mullard Replace- ment	BASE	CONVERSION
W2I	M	VP2	M	Join plns 3 and 4 together.
W42	М	VP4A	М	Rewire base.
W63	ĸ	EF39*	к	Bias may require adjustment.
X42	М	FC4	М	Bias may require adjustment.
X65	к	ECH35	к	Earth pin I. Receiver may require re- aligning.
YD2	Α	PM2A	A	Bias may require adjustment.
Y61	ĸ	EM34	K]	Supply a2 (pin 6) from H.T., through
Y62	ĸ	EM34	к }	IM Ω resistor,
Y63	К	EM34	ĸJ	Interchange connections, to pins 4 and 5.
Y220	0	PM22A	0	Bias may require adjustment.
Z2I	М	SP2	М	Earth pin 3.
IA4E	ŲΧ	KF35	k	Change base.
JA4P	UΧ	KF35	ĸ	Change base.
IA7G	к	DK32	ĸ	Earth pin I.
IC6	UX	KK32	ĸ	Change base.
IC7G	К	KK32	ĸ	Earth pin I.
ID5	0	URIC	0	Check Ih=0.2A.
ID6	UX	PY31	ĸ	Change base. Check Ih=0.3A.
ID7G	ĸ	KK32	ĸ	Earth pin 1.
IE5G	ĸ	KF35	ĸ	Earth pins I and 5.
IF4	UX	KL35	ĸ	Change base.
IH6G	ĸ	KBC32	ĸ	Rewire base.
ILA6	B8G	DK32	ĸ	Change base.
ILC5	B8G	DF33	ĸ	Change base.
ILDS	B8G	DAF91	B7G	Change base.
ILH4	B8G	DAC32	K	Change base.
ILN5	B8G	DF33	ĸ	Change base.
IN5G	K	DF33	ĸ	Change base.
154	B7G	DL92	B7G	Rewire base so that VI is between pin 5 and pins I and 7 connected together.
IUS	B7G	DAF91	B7G	Rewire base.
2D4	0	2D4A	0	Rewire base. 2D4A has no top-cap.
2D13	v	EB34	κì	Change base, when rewiring connect
2D13A	v	EB34	κ>	cathodes of EB34 together. EB34 : Vh
2D13C	o	EB34	$\left[\begin{array}{c} \hat{\kappa} \end{array}\right]$	=6·3V.
3Q4	B7G	DL94	B7G	Rewire base.
4DI	М	HL/3C	М	Earth pin I.
4THA	М	TH4B	М	Receiver may require realigning.
5Y3G	ĸ	GZ32	ĸ	GZ32 is indirectly heated.
5Y4G	ĸ	GZ32	ĸ	Rewire base. GZ32 is indirectly heated.
6A6	υx	ECC33	ĸ	Change base. ECC33 unsuitable for use as Class B output valve.
6A7	UX	EK32*	K)	Change base. Earth pin I. Receiver may
6A7E	UX	EK32*	κ}	require realigning.

^{*} See note at the beginning of Direct Equivalent Guide.

Type Number	BASE	Mullard Replace- ment	BASE	CONVERSION
6A8G	K	EK32*	К	Earth pin I. Receiver may require re- aligning.
6A8GT	к	EK32*	K	Receiver may require realigning.
6AK6	B7G	EL91	B7G	Rewire base.
6AT6	B7G	EBC4I	B8A	Change base.
6BD6	B7G	EF4I*	B8A	Change base.
6BT6	B7G	EBC4I*	B8A	Change base.
6C6	UX	EF37A*	K	Change base.
6D6	UX	EF39*	K	Change base.
6J7G	K	EF37A*	K	Earth pin I.
6]8G	K	ECH35	K	Earth pin I. Bias may require adjustment
6K7G	K	EF39*	K	Earth pin 1.
6K8G	К	ECH35	К	Earth pin I. Receiver may require re- aligning.
6K8GT	K	ECH35	K	Receiver may require realigning.
6L6G	к	EL37	K	Bias may require adjustment.
6N7GT/G	K	ECC33	K	Rewire base. ECC33 unsultable as Class E output valve.
6P28	K	EL38	K	Rewire base.
6Q7G	K	EBC33*	K	Earth pin I. Bias may require adjustment
6Q7GT	K	EBC33*	K	Bias may require adjustment.
657G	ĸ	EF39*	K	Earth pin I.
65C7	k	ECC35*	K	Rewire base.
6SJ7	К	EF36*	K	Rewire base.
6SK7	К	EF41*	B8A	Change base.
6SN7GT	к	ECC33	K	Blas may require adjustment.
6U5/6G5	UX	EM34*	K	Change base. Supply a 2 from H.T. through IM Ω resistor.
6U7G	K	EF39*	K	Earth pin I.
6V6G	K	EL33	K	Bias may require adjustment.
6W7G	K	EF37A*	K	Earth pin I.
6ZYSG	К	EZ35	K	EZ35 h=0.6A, 6ZY5G lh=0.3A.
7A7	B8G	EF22*	B8G	Blas may require adjustment.
7B7	B8G	EF22*	B8G	Blas may require adjustment.
7C5	B8G	EL4I	B8A	Change base. Bias may require adjust ment.
7F 7	B8G	ECC35*	K	Change base.
7K7	B8G	EBC4I	B8A	Change base.
757	B8G	ECH2I*	B8G	Rewire base. Receiver may require realigning.
7Y4	B8G	EZ35	k	Change base.
8D2	М	SP13C	M	Increase Vg2 to Va.
9D2	M	VPI3C	M	Earth pin 1. Raise Vg2 to 200V.
1001	0	EB34	К	Change base. When rewiring connect cathodes of EB34 together. EB34: V = 6.3V.

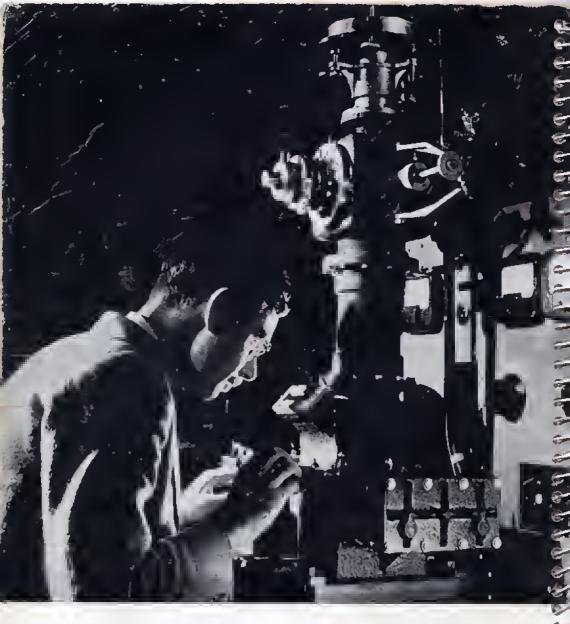
^{*}See note at the beginning of Direct Equivalent Guide.

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Type Number	BASE	Mullard Replace- ment	BASE	CONVERSION
IIA2	М	TDD4	М	Earth pin 2. Bias may require adjustment.
12Z3	UX	PY31	K	Change base. Check th=0.3A.
13PGA	М	FC13C	М	Vg2 max.=90V.
135PA	M	SPI3C	M	Increase Vg2 to Va.
13VPA	M	VPI3C	М	Increase Vg2 to Va.
15	UX	KF35	K	Change base.
5A2	M	FC4	M	Vg2 max.=90V.
15 D 1	M	FCI3C	M	Vg2 max.=90V.
25RE	UX	PY3I	К	Change base. Check Ih=0.3A. Only suitable as half-wave rectifier.
25Y5	ux	PY31	К	Change base. Check 1h=0.3A. Only suitable as half-wave rectifier.
25Z4G	K	PY31	K	Check Ih=0:3A.
25Z5	UX	PY3I	K	Change base. Check Ih=0.3A. Only suitable as half-wave rectifier.
25Z6G	К	PY31	K	Rewire base. Check Ih=0.3A. Only suitable as half-wave rectifier.
3SRE	UX	PZ30	K	Change base. Check Ih=0.3A.
36	UX	EF36*	K	Change base.
39/44	UX	EF39*	K	Change base.
40SUA	0	URIC	0	Check Ih=0.2A.
4 E	ux	EL32	K	Change base.
4ISTH	М	TH4B	M	Bias may require adjustment.
42/42E	UX	EL32	K	Change base.
45IU	Α	FW4/500	A	FW4/500 is directly heated.
77/77E	UX	EF37*	K	Change base.
7B/7BE	UX	EF39*	K	Change base.
80	UΧ	GZ32	K	Change base.
84/6Z4	UX	EZ35	K	Change base.
210LF	Α	PM2HL	A	Bias may require adjustment.
210SPT	М	SP2	M	Increase Vg2 to Va.
210VPT (4-pin)	0	VP2	M	Change base. Increase Vg2 to Va.
210VPT (7-pin)	M	VP2	M	Increase Vg2 to Va.
2159	Α	PM2A	Α	Increase VgI to -6V.
22 0 P	Α	PM2A	^	Bias will require adjustment.
2205G	A	PMI2M	A	Increase Vg2 to 90V.
230PT	A/O	PM22A	A/O	Change VgI to -4.5 V at Va=Vg2=135V and Ra to approximately 19K Ω .
230XP	Α	PM202	Α	Bias may require adjustment.
484V	0	354V	0	Change VgI to -4.5 V or Rk to 700Ω .
2101	UX	K L.35	K	Change base.
2102	UX	KBC32	К	Change base.

^{*} See note at the beginning of Direct Equivalent Gulde.



TECHNICAL DATA

